RICHTEK®

RT6252A/B

2A, 17V Input ACOT® Step-Down Converter with Overcurrent Protection for Both High-Side and Low-Side MOSFETs

1 General Description

The RT6252A/B is a simple, easy-to-use 2A synchronous step-down converter with an input supply voltage range of 4.5V to 17V. The device features an accurate reference voltage and integrates low R_{DSON} power MOSFETs to achieve high efficiency.

The RT6252A/B adopts Advanced Constant On-Time (ACOT®) control architecture to provide an ultrafast transient response with few external components and to operate at a nearly constant switching frequency over the line, load, and output voltage range. The RT6252A operates in automatic PSM, which maintains high efficiency during light load operation. The RT6252B operates in Forced PWM, which helps meet tight voltage regulation accuracy requirements.

The RT6252A/B senses the current through both the high-side and low-side MOSFETs for robust overcurrent protection (OCP). The device features cycle-by-cycle overcurrent protection to prevent the device from catastrophic damage in output short circuit, overcurrent, or inductor saturation conditions. A built-in soft-start function prevents inrush current during start-up. The device also includes input undervoltage-lockout, output undervoltage protection, and over-temperature protection (OTP) to provide safe and smooth operation in all operating conditions.

The recommended junction temperature range is –40°C to 125°C.

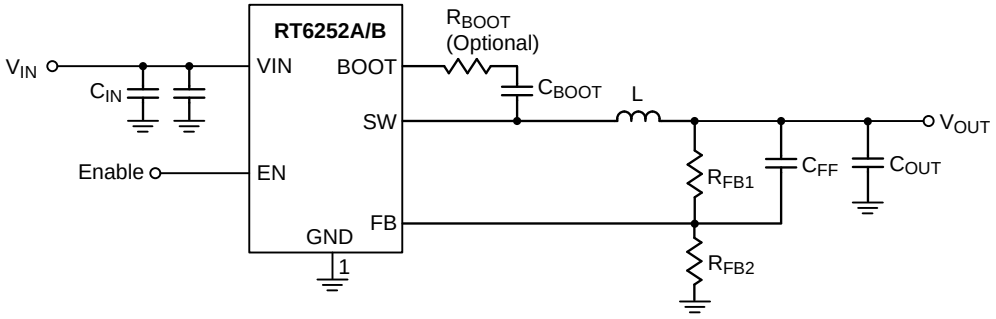
2 Features

- **2A Converter Integrated 140mΩ and 84mΩ MOSFETs**
- **Input Supply Voltage Range: 4.5V to 17V**
- **Output Voltage Range: 0.765V to 7V**
- **Advanced Constant On-Time (ACOT®) Control**
  - **Ultrafast Transient Response**
  - **Optimized for Low-ESR Ceramic Output Capacitors**
- **High Accuracy Feedback Reference Voltage: Typically ± 1%**
- **Optional Operation Modes:**
  - **RT6252A: Power Saving Mode (PSM)**
  - **RT6252B: Forced PWM Mode**
- **Fixed Switching Frequency: 580kHz**
- **Enable Control and Internally Fixed Soft-Start**
- **Safe Start-Up from Pre-Biased Output**
- **Input Undervoltage-Lockout (UVLO)**
- **Output Undervoltage Protection (UVP) with Hiccup Mode**
- **Overcurrent Protection (OCP) for High-Side and Low-Side MOSFETs and Over-Temperature Protection (OTP)**

3 Applications

- Set-Top Boxes
- LCD TVs
- Home Networking Devices
- Surveillance
- General Purpose

4 Simplified Application Circuit



Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

5 Ordering Information

RT6252A/B □□□

Package Type(1)
J6F: TSOT-23-6 (FC)
H6F: SOT-563 (FC)

Lead Plating System
G: Richtek Green Policy Compliant(2)

UVP Option
H: Hiccup

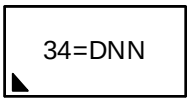
Operation Mode
A: Automatic PSM
B: Forced PWM

Note 1.

- Marked with (1) indicated: Compatible with the current requirements of IPC/JEDEC J-STD-020.
- Marked with (2) indicated: Richtek products are Richtek Green Policy compliant.

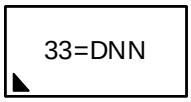
6 Marking Information

RT6252AHGJ6F



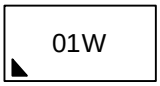
34= : Product Code
DNN : Date Code

RT6252BHGJ6F



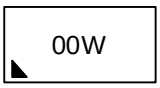
33= : Product Code
DNN : Date Code

RT6252AHGH6F



01 : Product Code
W : Date Code

RT6252BHGH6F



00 : Product Code
W : Date Code

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

Table of Contents

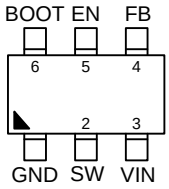
1 General Description ---- 1
2 Features ---- 1
3 Applications ---- 1
4 Simplified Application Circuit ---- 1
5 Ordering Information ---- 2
6 Marking Information ---- 2
7 Pin Configuration ---- 4
8 Functional Pin Description ---- 4
9 Functional Block Diagram ---- 5
10 Absolute Maximum Ratings ---- 6
11 ESD Ratings ---- 6
12 Recommended Operating Conditions ---- 6
13 Thermal Information ---- 7
14 Electrical Characteristics ---- 7
14.1 TSOT-23-6 (FC) ---- 7
14.2 SOT-563 (FC) ---- 9
15 Typical Application Circuit ---- 11
16 Typical Operating Characteristics ---- 12
17 Operation ---- 19
17.1 Advanced Constant On-Time Control and PWM Operation ---- 19
17.2 Power Saving Mode (RT6252A Only) ---- 19
17.3 Enable Control ---- 19
17.4 Soft-Start (SS) ---- 19
17.5 Pre-Bias ---- 20
17.6 Input Undervoltage-Lockout ---- 20
17.7 Output Undervoltage Protection and Hiccup Mode ---- 20
17.8 Overcurrent Protection ---- 21
17.9 Negative Overcurrent Limit ---- 21
17.10 Over-Temperature Protection ---- 21
18 Application Information ---- 23
18.1 Inductor Selection ---- 23
18.2 Input Capacitor Selection ---- 24
18.3 Output Capacitor Selection ---- 25
18.4 Output Ripple ---- 25
18.5 Output Transient Undershoot and Overshoot ---- 25
18.6 Output Voltage Setting ---- 26
18.7 Feed-Forward Capacitor Selection (C_{FF}) ---- 27
18.8 Enable Operation ---- 28
18.9 Bootstrap Driver Supply ---- 30
18.10 External Bootstrap Diode (Optional) ---- 30
18.11 External Bootstrap Resistor (Optional) ---- 30
18.12 Thermal Considerations ---- 31
18.13 Layout Considerations ---- 32
19 Outline Dimension ---- 34
19.1 TSOT-23-6 (FC) ---- 34
19.2 SOT-563 (FC) ---- 35
20 Footprint Information ---- 36
20.1 TSOT-23-6 (FC) ---- 36
20.2 SOT-563 (FC) ---- 37
21 Packing Information ---- 38
21.1 Tape and Reel Data ---- 38
21.2 Tape and Reel Packing ---- 40
21.3 Packing Material Anti-ESD Property ---- 42
22 Datasheet Revision History ---- 43

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

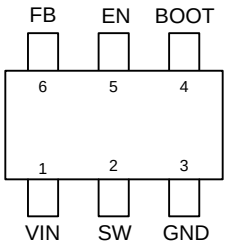
Downloaded from Arrow.com.

7 Pin Configuration

(TOP VIEW)



TSOT-23-6 (FC)



SOT-563 (FC)

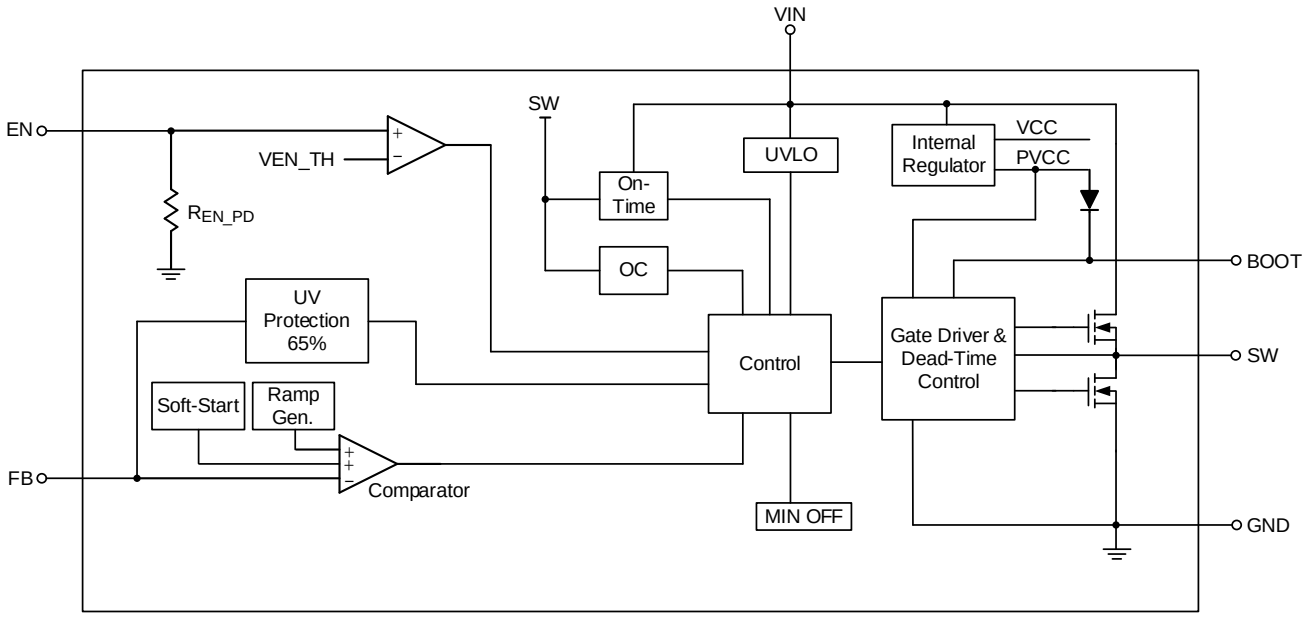
8 Functional Pin Description

Pin No.		Pin Name	Pin Function
TSOT23-6 (FC)	SOT-563 (FC)		
1	3	GND	Power ground.
2	2	SW	Switch node between the internal switch and the synchronous rectifier. Connect this pin to the inductor and bootstrap capacitor.
3	1	VIN	Power input. The input voltage range is from 4.5V to 17V. Connect input bypass capacitors directly to this pin and the GND pins. An MLCC with a capacitance higher than 20μF is recommended.
4	6	FB	Feedback voltage input. Connect this pin to the midpoint of the external feedback resistive divider to set the output voltage of the converter to the desired regulation level. The device regulates the FB voltage at the feedback reference voltage.
5	5	EN	Enable control input. Connecting this pin to logic high enables the device, and connecting this pin to GND disables the device.
6	4	BOOT	Bootstrap capacitor connection node to supply the high-side gate driver. Connect a 0.1μF ceramic capacitor between this pin and the SW pin.

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

9 Functional Block Diagram



Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

10 Absolute Maximum Ratings

(Note 2)

- Supply Input Voltage, VIN ---------- –0.3V to 20V
- Enable Voltage, EN ---------- –0.3V to 20V
- Switch Voltage, SW ---------- –0.3V to 20.3V

  < 100ns ---------- –5V to 25V
- BOOT Voltage, BOOT ---------- – 0.3V to 26V
- BOOT to SW, $V_{BOOT} – V_{SW}$ ---------- –0.3V to 6V
- Feedback Voltage, FB ---------- –0.3V to 6V
- Lead Temperature (Soldering, 10 sec.) ---------- 260°C
- Junction Temperature ---------- 150°C
- Storage Temperature Range ---------- –65°C to 150°C

Note 2. Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

11 ESD Ratings

(Note 3)

- ESD Susceptibility

  HBM (Human Body Model) ---------- 2kV

Note 3. Devices are ESD sensitive. Handling precautions are recommended.

12 Recommended Operating Conditions

(Note 4)

- Supply Input Voltage ---------- 4.5V to 17V
- Junction Temperature Range ---------- –40°C to 125°C

Note 4. The device is not guaranteed to function outside its operating conditions.

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

13 Thermal Information

(Note 5 and Note 6)

Thermal Parameter		TSOT-23-6 (FC)	SOT-563 (FC)	Unit
θ_{JA}	Junction-to-ambient thermal resistance (JEDEC standard)	88.7	104.3	°C/W
$\theta_{JC(Top)}$	Junction-to-case (top) thermal resistance	76.9	62.1	°C/W
$\theta_{JC(Bottom)}$	Junction-to-case (bottom) thermal resistance	6	8.4	°C/W
$\theta_{JA(EVB)}$	Junction-to-ambient thermal resistance (specific EVB)	63.3	82.3	°C/W
$\Psi_{JC(Top)}$	Junction-to-top characterization parameter	15.3	7.5	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	34.66	47.38	°C/W

Note 5. θ_{JA} and θ_{JC} are simulated or simulated at T_A = 25°C based on the JEDEC 51-7 standard.

Note 6. $\theta_{JA(EVB)}$, $\Psi_{JC(TOP)}$, and Ψ_{JB} are simulated on a high effective-thermal-conductivity four-layer test board which is in size of 70mm x 50mm; furthermore, all layers with 1 oz. Cu. Thermal resistance/parameter values may vary depending on the PCB material, layout, and test environmental conditions.

14 Electrical Characteristics

14.1 TSOT-23-6 (FC)

(V_{IN} = 12V, T_A = 25°C, unless otherwise specified.)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Supply Voltage						
VIN Supply Input Voltage	V_{IN}		4.5	--	17	V
Undervoltage-Lockout Threshold	V_{UVLO}		3.7	4	4.3	V
Undervoltage-Lockout Threshold Hysteresis	V_{UVOL_HYS}		--	400	--	mV
Shutdown Current	I_{SHDN}	V_{EN} = 0V	--	--	4	μA
Quiescent Current	I_Q	V_{EN} = 2V, V_{FB} = 0.8V	--	280	--	μA
Soft-Start						
Soft-Start Time	t_{SS}		--	1	--	ms
Enable Voltage						
EN Input Voltage Rising Threshold	V_{EN_R}		1.16	1.25	1.34	V
EN Input Voltage Falling Threshold	V_{EN_F}		1.01	1.1	1.19	
EN Pin Pull-Down Resistance	R_{EN_PD}	EN pin resistance to GND, V_{EN} = 12V	225	450	900	kΩ
Feedback Voltage and Discharge Resistance						
Feedback Voltage	V_{FB}	V_{OUT} = 1.05V	758	765	772	mV
FB Pin Current	I_{FB}	V_{FB} = 0.8V, T_A = 25°C	–0.1	0	0.1	μA

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Internal MOSFET						
On-Resistance of High-Side MOSFET	R_{DSON_H}	$V_{BOOT} – V_{SW}$ = 4.8V	--	140	--	mΩ
On-Resistance of Low-Side MOSFET	R_{DSON_L}		--	84	--	
Current Limit						
High-Side Switch Current Limit	I_{LIM_H}		--	5	--	A
Low-Side Switch Current Limit	I_{LIM_L}		2.2	3.2	4.2	
Low-Side Switch Negative Current Limit	I_{NOC}	Forced PWM mode only	--	1.45	--	A
Switching Frequency						
Switching Frequency	f_{SW}	V_{OUT} = 1.05V, PWM mode	--	580	--	kHz
On-Time Timer Control						
Minimum On-Time	t_{ON_MIN}		--	60	--	ns
Minimum Off-Time	t_{OFF_MIN}	V_{FB} = 0.5V	--	200	260	ns
Output Undervoltage Protections						
Output Undervoltage Protection Threshold	V_{UVP}	Hiccup detect	--	65	--	%
Hiccup Power On-Time	t_{HICCUP_ON}		--	1.8	--	ms
Hiccup Power Off-Time	t_{HICCUP_OFF}		--	15	--	
Over-Temperature Protection						
Over-Temperature Protection Threshold	T_{OTP}		--	155	--	°C
Over-Temperature Protection Hysteresis	T_{OTP_HYS}		--	35	--	

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

14.2 SOT-563 (FC)

(V_{IN} = 12V, T_A = 25°C, unless otherwise specified.)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Supply Voltage						
VIN Supply Input Voltage	V_{IN}		4.5	--	17	V
Undervoltage-Lockout Threshold	V_{UVLO}		3.9	4.2	4.5	V
Undervoltage-Lockout Threshold Hysteresis	V_{UVOL_HYS}		--	420	--	mV
Shutdown Current	I_{SHDN}	V_{EN} = 0V	--	--	4	μA
Quiescent Current	I_Q	V_{EN} = 2V, V_{FB} = 0.85V	--	295	--	μA
Soft-Start						
Soft-Start Time	t_{SS}		--	0.95	--	ms
Enable Voltage						
EN Input Voltage Rising Threshold	V_{EN_R}		1.24	1.31	1.38	V
EN Input Voltage Falling Threshold	V_{EN_F}		1.09	1.16	1.23	
EN Pin Pull-Down Resistance	R_{EN_PD}	EN pin resistance to GND, V_{EN} = 12V	225	450	900	kΩ
Feedback Voltage and Discharge Resistance						
Feedback Voltage	V_{FB}	V_{OUT} = 1.05V	799	807	815	mV
FB Pin Current	I_{FB}	V_{FB} = 0.85V, T_A = 25°C	–0.1	0	0.1	μA
Internal MOSFET						
On-Resistance of High-Side MOSFET	R_{DSON_H}	V_{BOOT} – V_{SW} = 4.8V	--	140	--	mΩ
On-Resistance of Low-Side MOSFET	R_{DSON_L}		--	84	--	
Current Limit						
High-Side Switch Current Limit	I_{LIM_H}		--	5	--	A
Low-Side Switch Current Limit	I_{LIM_L}		2.5	3.35	4.2	
Low-Side Switch Negative Current Limit	I_{NOC}	Forced PWM mode only	--	1.35	--	A
Switching Frequency						
Switching Frequency	f_{SW}	V_{OUT} = 1.05V, PWM mode	--	580	--	kHz
On-Time Timer Control						
Minimum On-Time	t_{ON_MIN}		--	60	--	ns
Minimum Off-Time	t_{OFF_MIN}	V_{FB} = 0.5V	--	190	250	ns
Output Undervoltage Protections						
Output Undervoltage Protection Threshold	V_{UVP}	Hiccup detect	--	65	--	%
Hiccup Power On-Time	t_{HICCUP_ON}		--	1.8	--	ms

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Hiccup Power Off-Time	t_{HICCUP_OFF}		--	15	--	
Over-Temperature Protection						
Over-Temperature Protection Threshold	T_{OTP}		--	155	--	°C
Over-Temperature Protection Hysteresis	T_{OTP_HYS}		--	35	--	

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

15 Typical Application Circuit

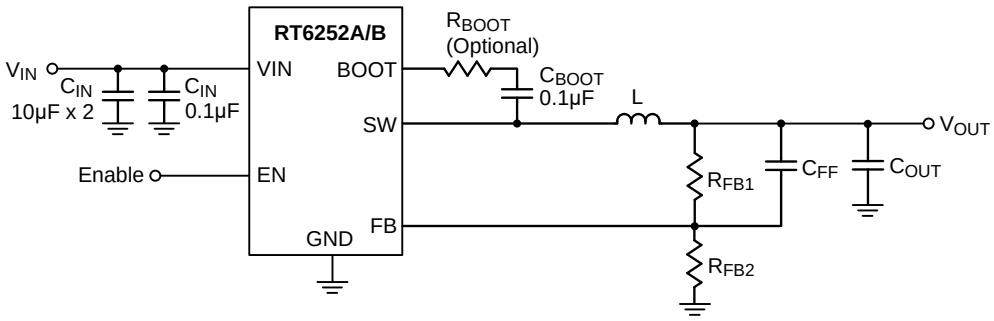


Table 1. Recommended Components Selection

V_{OUT} (V)	R_{FB1} (kΩ)		R_{FB2} (kΩ)	C_{FF} (pF)	L (µH)	C_{OUT} (µF)
	TSOT-23-6 (FC)	SOT-563 (FC)				
5.0	54.9	52.3	10	10 to 100	3.3 to 4.7	20 to 68
3.3	33.2	30.9	10	10 to 100	3.3 to 4.7	20 to 68
2.5	22.6	21	10	10 to 100	3.3 to 4.7	20 to 68
1.8	13.7	12.4	10	10 to 100	2.2 to 4.7	20 to 68
1.5	9.53	8.66	10	--	2.2 to 4.7	20 to 68
1.2	5.76	4.87	10	--	2.2 to 4.7	20 to 68
1.0	3.09	2.4	10	--	2.2 to 4.7	20 to 68

Note 7.

- Do not use a C_{FF} higher than 100pF due to the noise coupling consideration.
- Considering the effective capacitance de-rating, which is related to the biased voltage level and the size of the capacitor, the effective capacitance of C_{OUT} at the target output level should meet the value in above table to ensure stable and normal operation of the converter.

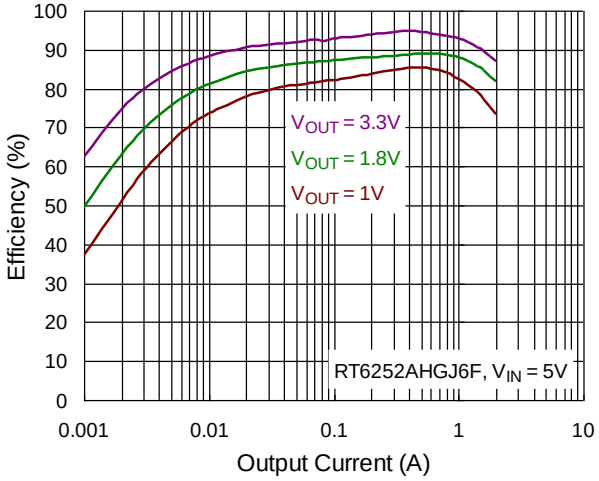
Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

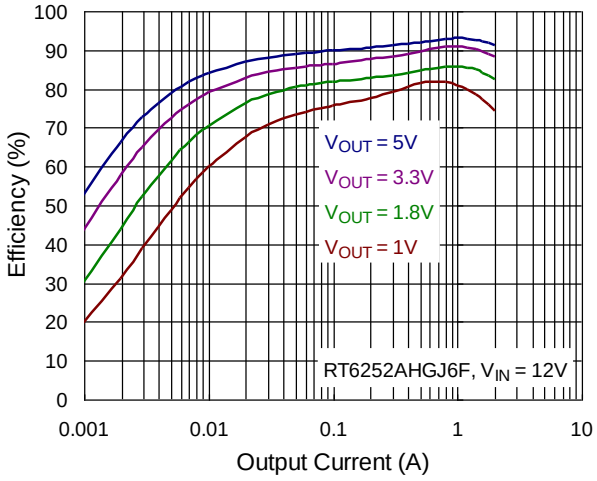
16 Typical Operating Characteristics

L: WE-74404054022 (DCR = 19mΩ) for V_{OUT} = 1V and 1.8V.
L: WE-74404054047 (DCR = 30mΩ) for V_{OUT} = 3.3V and 5V.

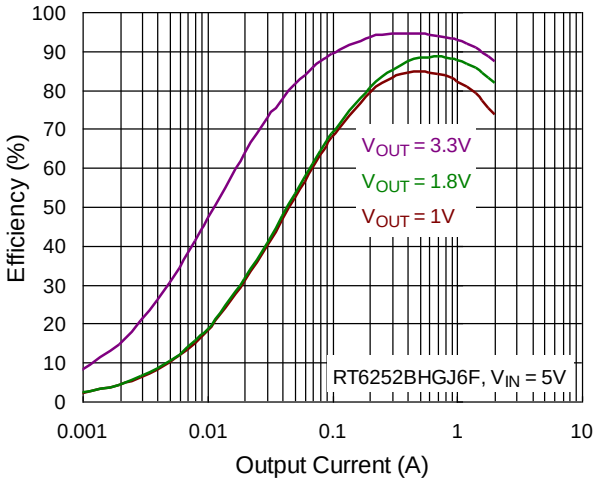
Efficiency vs. Output Current



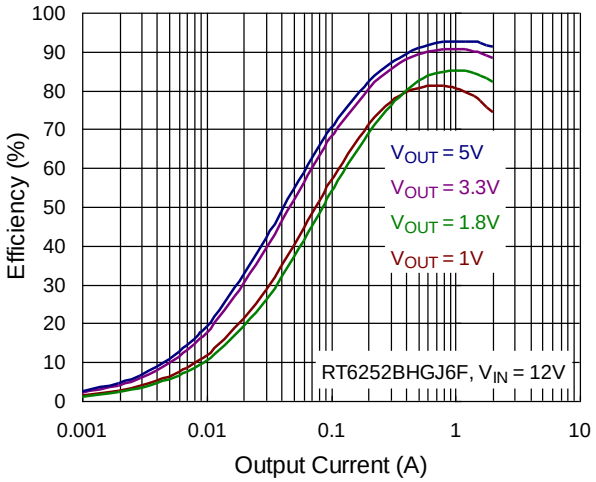
Efficiency vs. Output Current



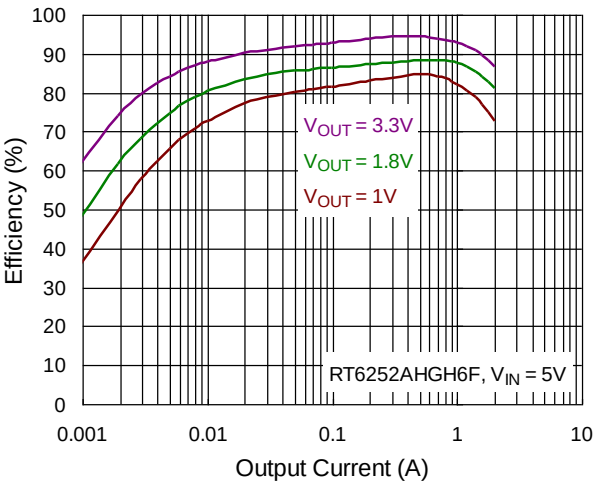
Efficiency vs. Output Current



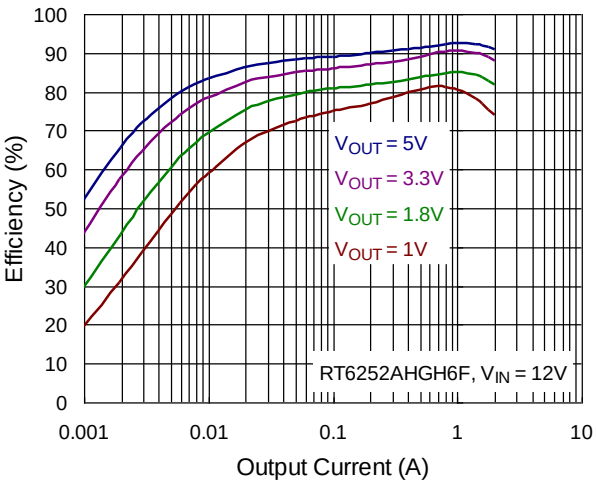
Efficiency vs. Output Current



Efficiency vs. Output Current



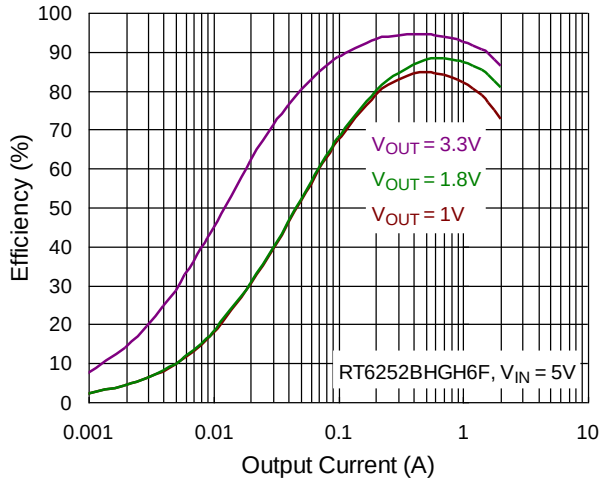
Efficiency vs. Output Current



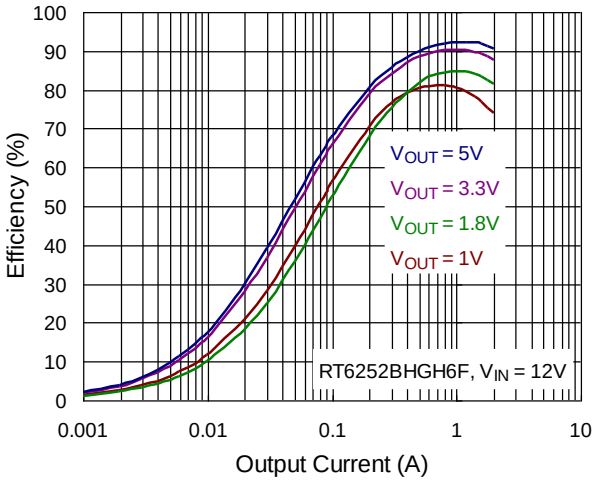
Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

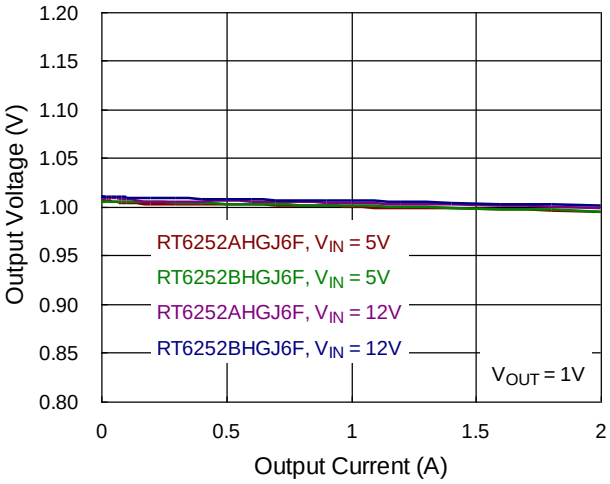
Efficiency vs. Output Current



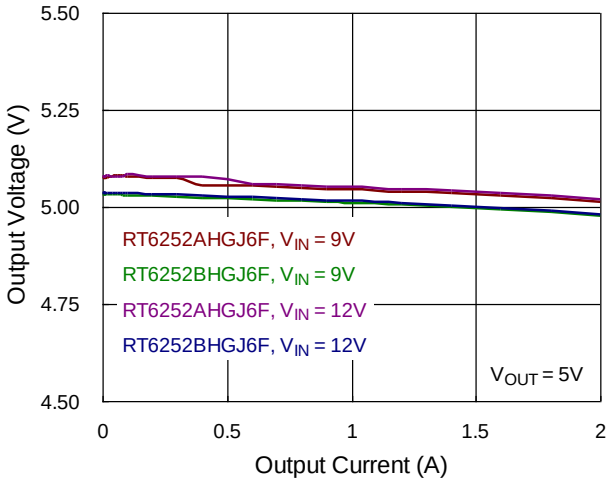
Efficiency vs. Output Current



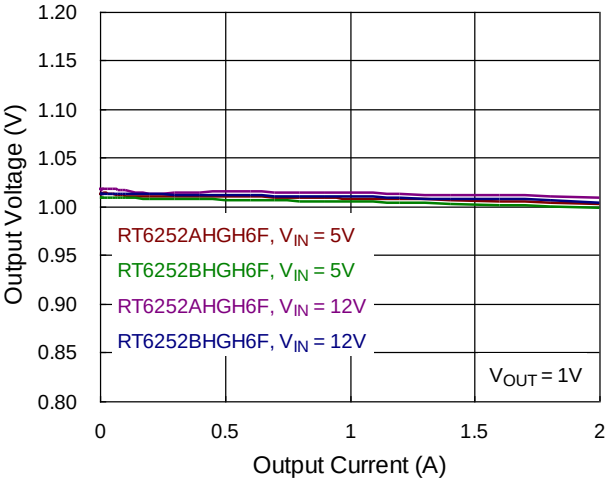
Output Voltage vs. Output Current



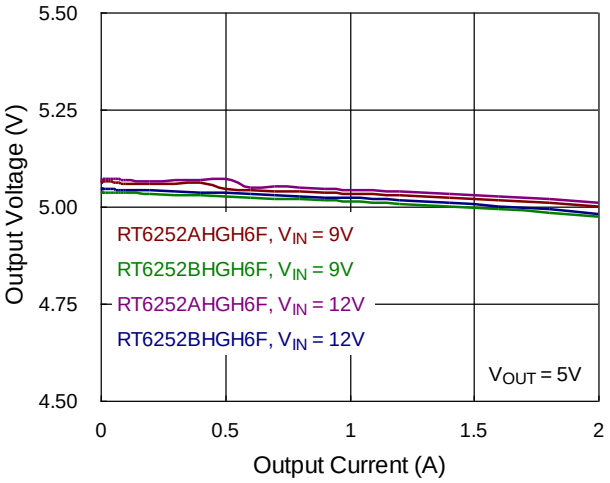
Output Voltage vs. Output Current



Output Voltage vs. Output Current



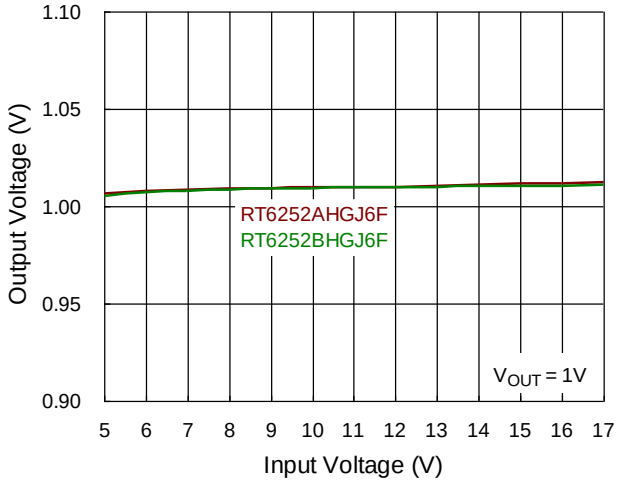
Output Voltage vs. Output Current



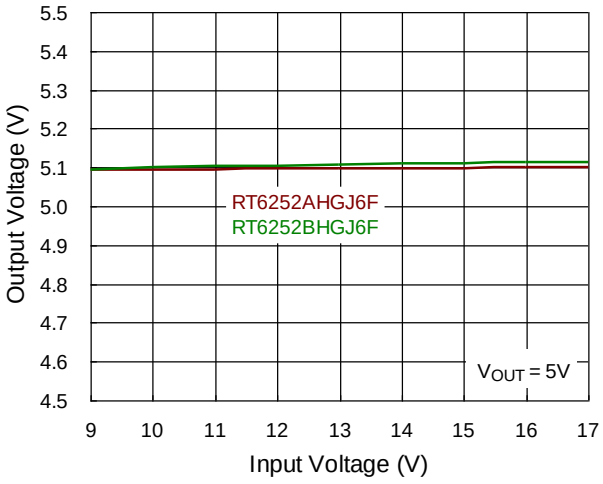
Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

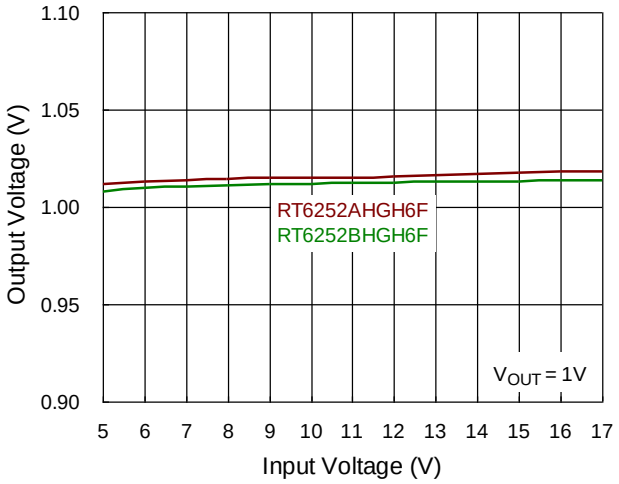
Output Voltage vs. Input Voltage



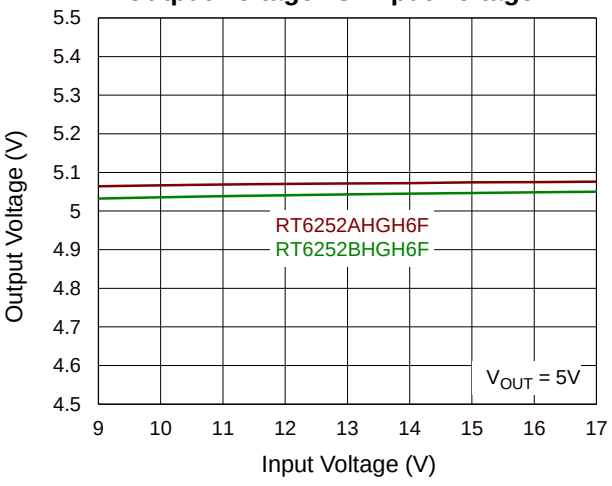
Output Voltage vs. Input Voltage



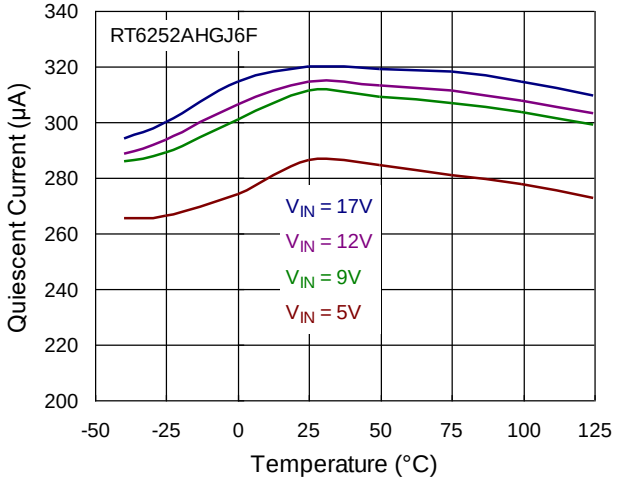
Output Voltage vs. Input Voltage



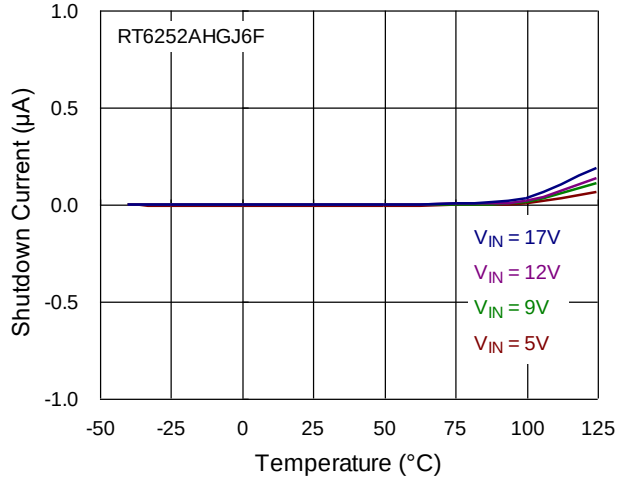
Output Voltage vs. Input Voltage



Quiescent Current vs. Temperature



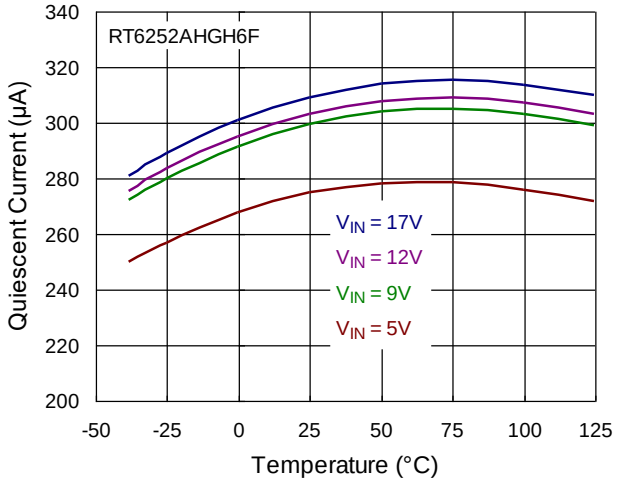
Shutdown Current vs. Temperature



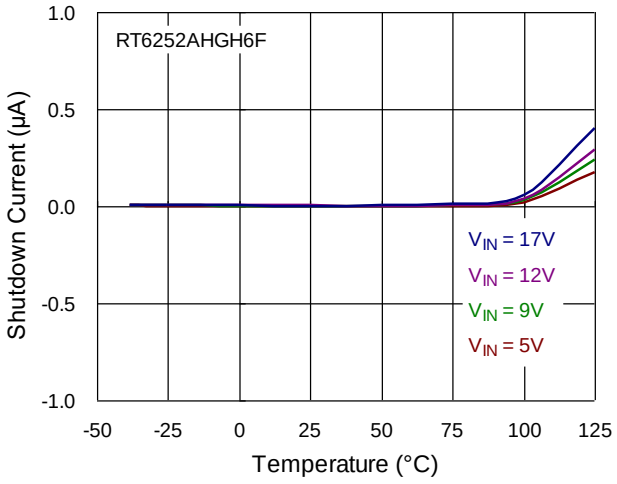
Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

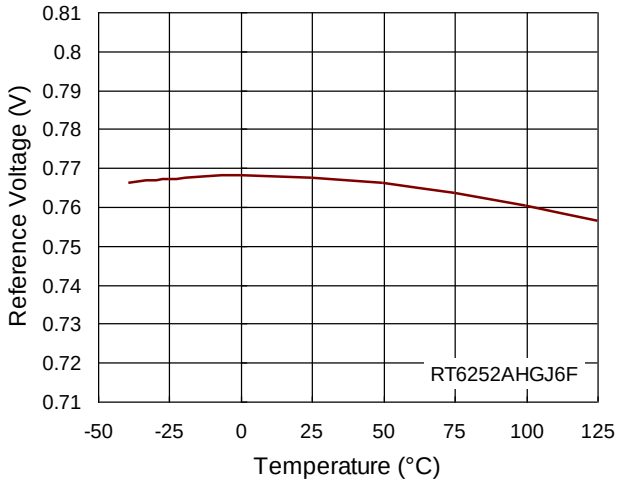
Quiescent Current vs. Temperature



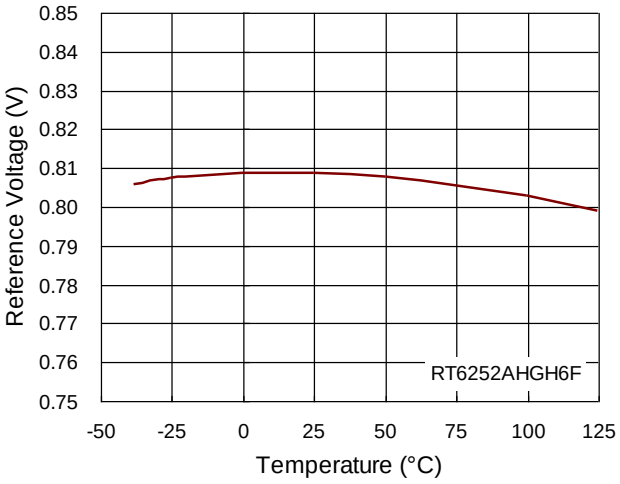
Shutdown Current vs. Temperature



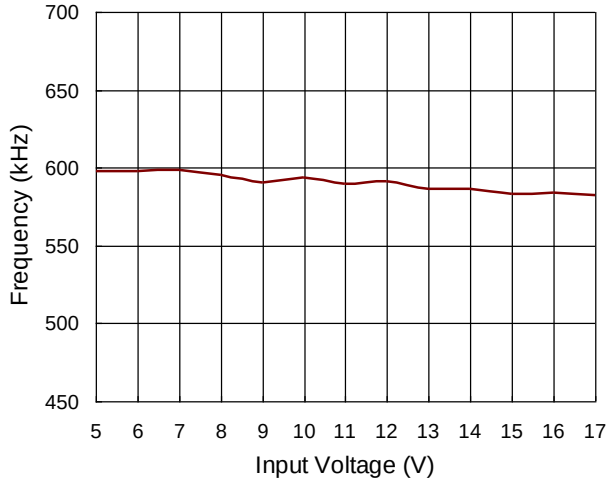
Reference Voltage vs. Temperature



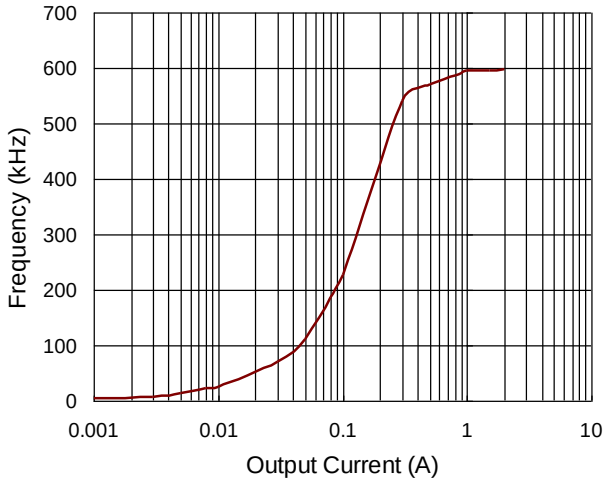
Reference Voltage vs. Temperature



Frequency vs. Input Voltage



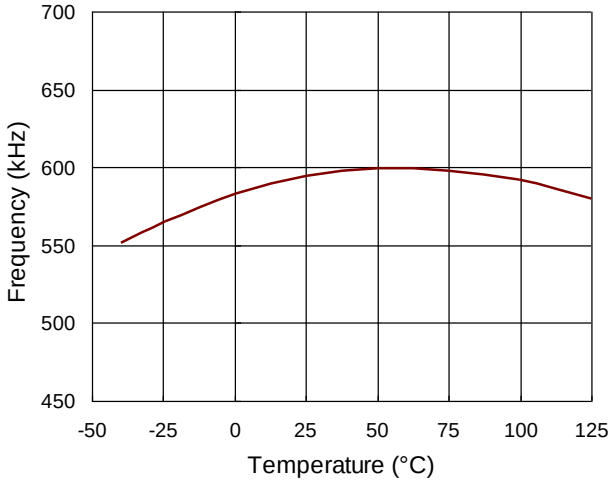
Frequency vs. Output Current



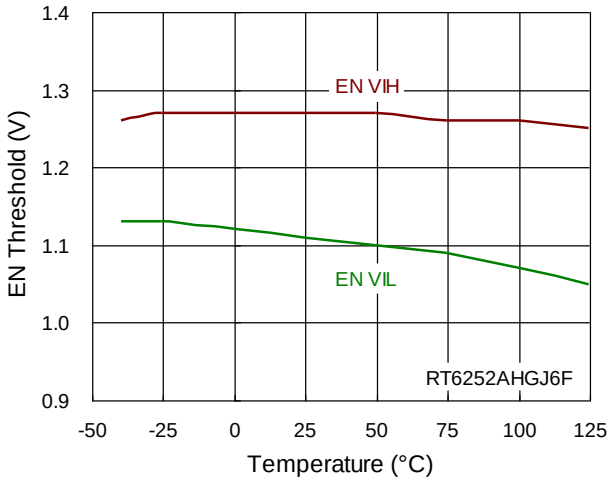
Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

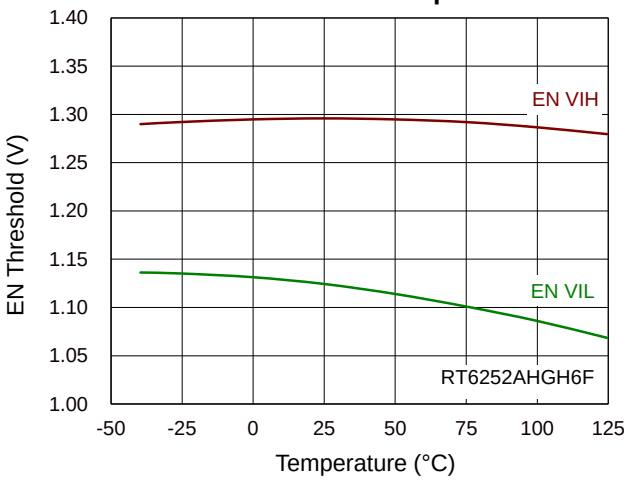
Frequency vs. Temperature



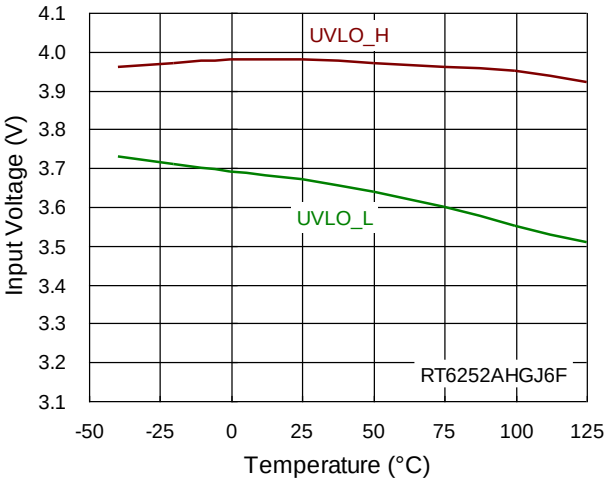
EN Threshold vs. Temperature



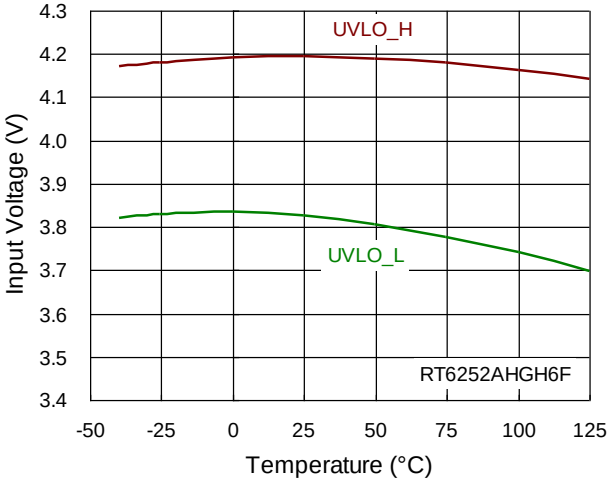
EN Threshold vs. Temperature



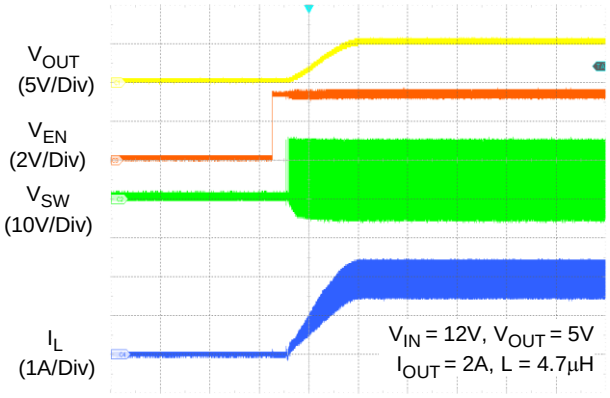
UVLO vs. Temperature



UVLO vs. Temperature



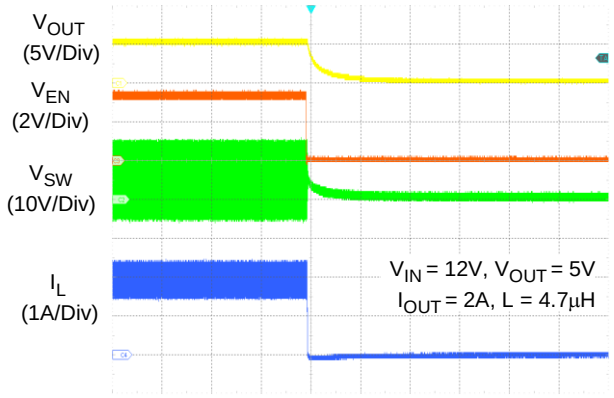
Power On from EN



Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

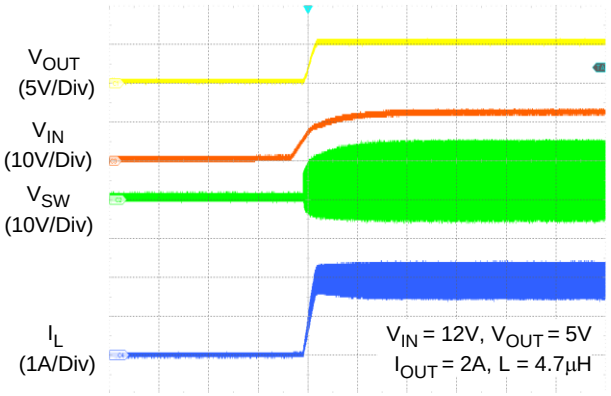
Downloaded from Arrow.com.

Power Off from EN



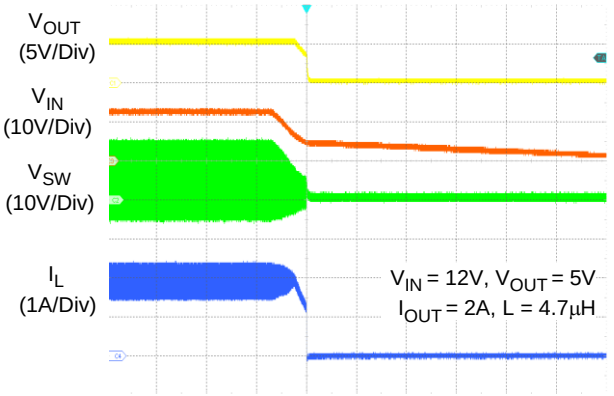
Time (200µs/Div)

Power On from VIN



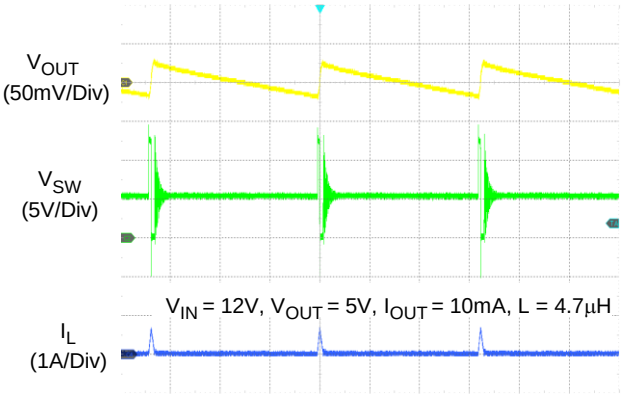
Time (5ms/Div)

Power Off from VIN



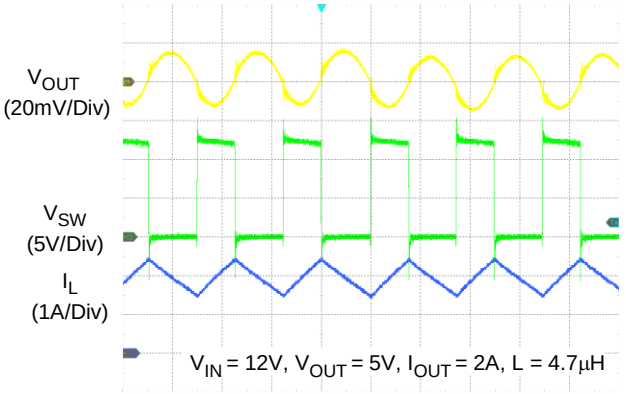
Time (5ms/Div)

Output Ripple as I_{OUT} = 10mA



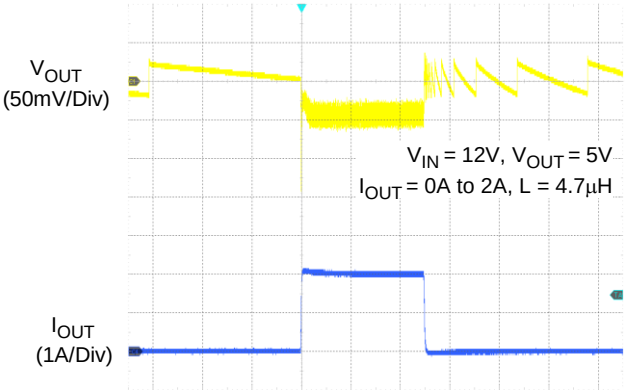
Time (10µs/Div)

Output Ripple as I_{OUT} = 2A



Time (1µs/Div)

Load Transient (No Load to Full Load)

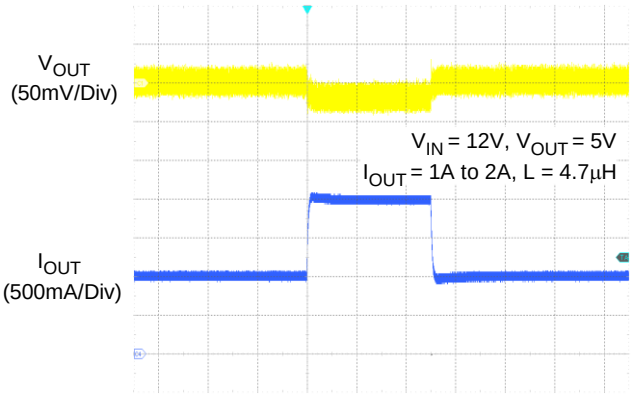


Time (400µs/Div)

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

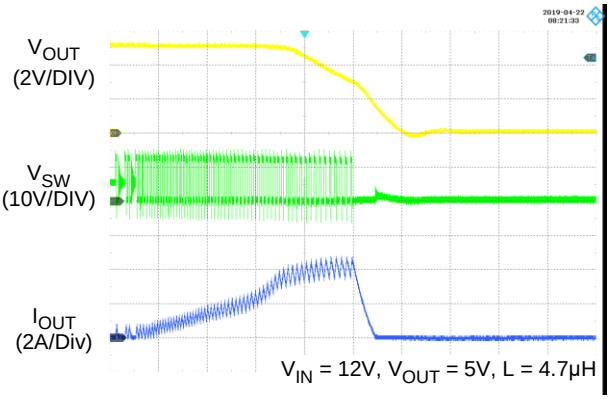
Downloaded from Arrow.com.

Load Transient (Half Load to Full Load)



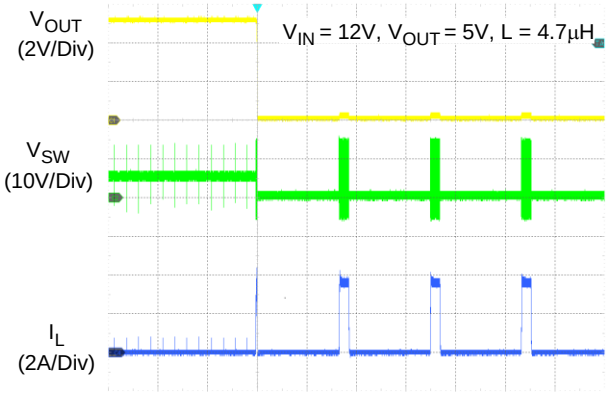
Time (400µs/Div)

Overcurrent Protection and UVP



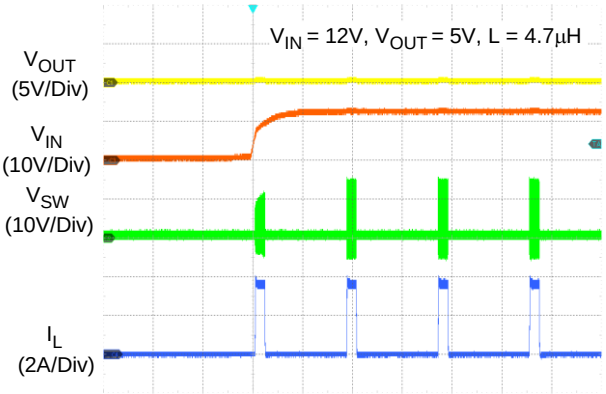
Time (20µs/Div)

Short Circuit Protection



Time (10ms/Div)

Short Circuit before Power On



Time (10ms/Div)

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

17 Operation

The RT6252A/B is a high-efficiency, synchronous step-down converter that can deliver up to 2A output current from a 4.5V to 17V input voltage.

17.1 Advanced Constant On-Time Control and PWM Operation

The RT6252A/B adopts ACOT® control for its ultrafast transient response, low external component count, and stability with low ESR MLCC output capacitors. When the feedback voltage falls below the feedback reference voltage, the minimum off-time one-shot (200ns, typical) has timed out and the inductor current is below the current-limit threshold, then the internal on-time one-shot circuitry is triggered, and the high-side switch is turned on. Since the minimum off-time is short, the device exhibits an ultrafast transient response and enables the use of smaller output capacitance.

The on-time is inversely proportional to the input voltage and directly proportional to the output voltage to achieve a pseudo-fixed frequency over the input voltage range. After the on-time one-shot timer expires, the high-side switch is turned off, and the low-side switch is turned on until the on-time one-shot is triggered again. To achieve stable operation with low ESR ceramic output capacitors, an internal ramp signal is added to the feedback reference voltage to simulate the output voltage ripple.

17.2 Power Saving Mode (RT6252A Only)

The RT6252A automatically enters power saving mode (PSM) at light load to maintain high efficiency. As the load current decreases, the inductor current ripple valley eventually touches the zero current, which is the boundary between continuous conduction and discontinuous conduction modes. The low-side switch is turned off when the zero inductor current is detected. In this case, the output capacitor is only discharged by the load current so that the switching frequency decreases. As a result, the light-load efficiency can be enhanced due to lower switching loss.

17.3 Enable Control

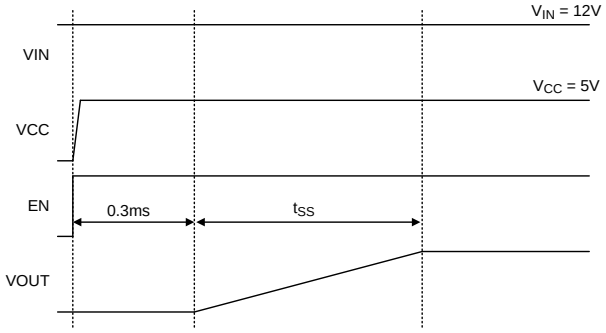
The RT6252A/B provides an EN pin as an external chip enable control to enable or disable the device. If V_{EN} is held below the logic-low threshold voltage (V_{EN_F}) of the enable input (EN), the converter will disable the output voltage; that is, the converter is disabled, and switching is inhibited even if the VIN voltage is above the VIN undervoltage-lockout threshold (V_{UVLO}). During shutdown mode, the supply current can be reduced to I_{SHDN} (10μA or below). If the EN voltage rises above the logic-high threshold voltage (V_{EN_R}) while the VIN voltage is higher than the UVLO threshold, the device will be turned on; that is, switching is enabled, and soft-start sequence is initiated. An internal resistor R_{EN_PD} from EN to GND allows the EN pin to float, shutting down the chip. See Enable Operation.

17.4 Soft-Start (SS)

The RT6252A/B provides an internal soft-start feature to control inrush current, and the output voltage starts to rise 0.3ms after the EN rising edge. At power-up, the internal capacitor is charged by an internal current source to generate a soft-start ramp voltage, which serves as a reference voltage to the PWM comparator. The device will initiate switching, and the output voltage will smoothly ramp up to its targeted regulation voltage only after this ramp voltage is greater than the feedback voltage V_{FB}, ensuring the converter has a smooth start-up from a pre-biased output.

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.



17.5 Pre-Bias

If there is a residual voltage on the output voltage before start-up, both the internal HSFET and LSFET are prohibited from switching until the internal V_{REF} ramps up higher than the feedback voltage. When the soft-start ramp is higher than the feedback voltage, switching will begin, and the output voltage will smoothly rise from the pre-biased level to its regulated target.

17.6 Input Undervoltage-Lockout

In addition to the EN pin, the RT6252A/B also provides enable control via the VIN pin. It features an undervoltage-lockout (UVLO) function that monitors the internal linear regulator voltage (VCC). If V_{EN} rises above V_{EN_R} first, switching will still be inhibited until the VIN voltage rises above V_{UVLO}. This ensures that the internal regulator is ready, preventing operation with not-fully-enhanced internal MOSFET switches. After the device is powered up, if the input voltage VIN goes below the UVLO falling threshold voltage ($V_{UVLO} - V_{UVLO_HYS}$), switching will be inhibited; if VIN rises above the UVLO rising threshold (V_{UVLO}), the device will resume normal operation with a complete soft-start.

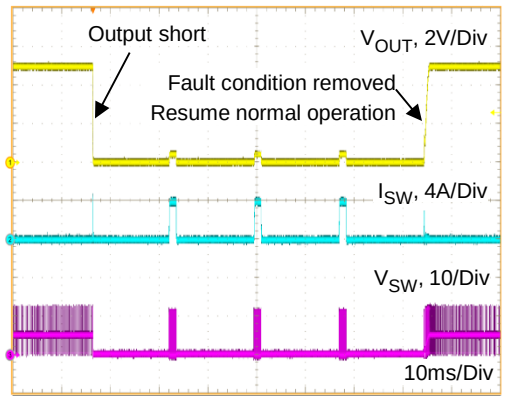
17.7 Output Undervoltage Protection and Hiccup Mode

The RT6252A/B includes output undervoltage protection (UVP) against overload or short-circuit conditions by constantly monitoring the feedback voltage (V_{FB}). If V_{FB} drops below the undervoltage protection trip threshold, typically 65% of the internal feedback reference voltage, the UV comparator will go high, turning off both the internal high-side and low-side MOSFET switches.

If the output undervoltage condition persists for a period of time, the RT6252A/B will enter output undervoltage protection in hiccup mode. During hiccup mode, the IC will shut down for t_{HICCUP_OFF} (15ms) and then attempt to recover automatically for t_{HICCUP_ON} (1.8ms). Upon completion of the soft-start sequence, if the fault condition is removed, the converter will resume normal operation; otherwise, the auto-recovery cycle will be repeated until the fault condition is cleared. The hiccup mode allows the circuit to operate safely with low input current and low power dissipation, and then the converter resumes normal operation as soon as the overload or short-circuit condition is removed.

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.



17.8 Overcurrent Protection

The RT6252A/B features cycle-by-cycle overcurrent protection on both the high-side and low-side MOSFETs and prevents the device from catastrophic damage in output short-circuit, overcurrent, or inductor saturation conditions.

The high-side MOSFET overcurrent protection is achieved by an internal current comparator that monitors the current in the high-side MOSFET during each on-time. The switch current is compared with the high-side switch current limit (I_{LIM_H}) after a certain delay when the high-side switch is turned on each cycle. If an overcurrent condition occurs, the converter will immediately turn off the high-side switch and turn on the low-side switch to prevent the inductor current exceeding the high-side current limit.

The low-side MOSFET overcurrent protection is achieved by measuring the inductor current through the synchronous rectifier (low-side switch) during the low-side on-time. Once the current rises above the low-side switch current limit (I_{LIM_L}), the on-time one-shot will be inhibited until the inductor current ramps down to the current limit level (I_{LIM_L}), that is, another on-time can only be triggered when the inductor current goes below the low-side current limit. If the output load current exceeds the available inductor current (which is clamped by the low-side current limit), the output capacitor needs to supply the extra current, causing the output voltage to begin to drop. If the output voltage drops below the output undervoltage protection trip threshold, the IC will stop switching to avoid excessive heat.

17.9 Negative Overcurrent Limit

The RT6252B is forced to PWM and allows for negative current operation.

In case of PWM operation, high negative current may be generated if an external power source is unexpectedly tied to the output terminal.

Due to the risk described above, the internal circuit monitors the negative current during each on-time interval of the low-side MOSFET and compares it with the NOC threshold.

Once the negative current exceeds the NOC threshold, the low-side MOSFET is turned off immediately, and then the high-side MOSFET will be turned on to discharge the energy of the output inductor. This behavior can keep the valley of the negative current at the NOC threshold to protect the low-side MOSFET. However, the negative current cannot be limited to the NOC threshold once the minimum off-time is reached.

17.10 Over-Temperature Protection

The RT6252A/B includes over-temperature protection (OTP) circuitry to prevent overheating due to excessive power dissipation. The OTP will shut down the switching operation when the junction temperature exceeds the over-temperature protection threshold (T_{OTP}). Once the junction temperature cools down by the over-temperature

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

protection hysteresis (T_{OTP_HYS}), the IC will resume normal operation with a complete soft-start.

Note that the over-temperature protection is intended to protect the device during momentary overload conditions. The protection is activated outside the absolute maximum range of operation as a secondary fail-safe and therefore should not be relied upon for operational purposes. Continuous operation above the specified absolute maximum operating junction temperature may impair the reliability of the device or permanently damage it.

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

18 Application Information

(Note 8)

The output stage of a synchronous buck converter is composed of an inductor and capacitor, which store and deliver energy to the load, and form a second-order low-pass filter to smooth out the switch node voltage and maintain a regulated output voltage.

18.1 Inductor Selection

Inductor selection involves trade-offs among size, cost, efficiency, and transient response requirements. Generally, three key inductor parameters are specified for operation with this device: inductance value (L), inductor saturation current (I_{SAT}), and DC resistance (DCR).

A good compromise between size and loss is to choose the peak-to-peak ripple current equal to 20% to 50% of the IC's rated current. The switching frequency, input voltage, output voltage, and selected inductor ripple current determine the inductor value as follows:

$$L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times f_{SW} \times \Delta I_L}$$

Once the inductor value is chosen, the ripple current (ΔI_L) is calculated to determine the required peak inductor current.

$$\Delta I_L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times f_{SW} \times L} \text{ and } I_{L(PEAK)} = I_{OUT(MAX)} + \frac{\Delta I_L}{2}$$

$I_{L(PEAK)}$ should not exceed the minimum value of the IC's upper current limit level. Additionally, the current flowing through the inductor is the sum of the inductor ripple current and the output current. During power-up, faults, or transient load conditions, the inductor current can increase above the peak inductor current level calculated above. In transient conditions, the inductor current can increase up to the device's switch current limit. For this reason, the most conservative approach is to specify an inductor with a saturation current rating that is equal to or greater than the switch current limit rather than the peak inductor current.

Considering the typical application circuit for a 1.2V output at 2A and an input voltage of 12V, and using an inductor ripple of 0.8A (40% of the IC's rated current), the calculated inductance value is:

$$L = \frac{1.2 \times (12 - 1.2)}{12 \times 580kHz \times 0.8A} = 2.33\mu H$$

For the typical application, a standard inductance value of 2.2μH can be selected.

$$\Delta I_L = \frac{1.2 \times (12 - 1.2)}{12 \times 580kHz \times 2.2\mu H} = 0.85A \text{ (42.5\% of the IC rated current)}$$

$$\text{and } I_{L(PEAK)} = 2A + \frac{0.85A}{2} = 2.425A$$

For the 2.2μH value, the inductor's saturation and thermal rating should be at least 2.454A. For a more conservative approach, the rating for inductor saturation current must be equal to or greater than the switch current limit of the device rather than the inductor peak current.

For EMI-sensitive applications, choosing a shielded type inductor is preferred.

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

18.2 Input Capacitor Selection

Input capacitance, C_{IN}, is needed to filter the pulsating current at the drain of the high-side power MOSFET. C_{IN} should be sized to achieve this without causing a large variation in input voltage. The waveforms of C_{IN} ripple voltage and ripple current are shown in Figure 1. The peak-to-peak voltage ripple on the input capacitor can be estimated using the equation below:

$$\Delta V_{CIN} = D \times I_{OUT} \times \left(\frac{1-D}{C_{IN} \times f_{SW}} \right) + I_{OUT} \times ESR$$

where

$$D = \frac{V_{OUT}}{V_{IN} \times \eta}$$

For ceramic capacitors, the equivalent series resistance (ESR) is very low, so the ripple caused by ESR can be ignored, and the minimum input capacitance can be estimated using the equation below:

$$C_{IN_MIN} = I_{OUT_MAX} \times \frac{D(1-D)}{\Delta V_{CIN_MAX} \times f_{SW}}$$

where $\Delta V_{CIN_MAX} \leq 200mV$

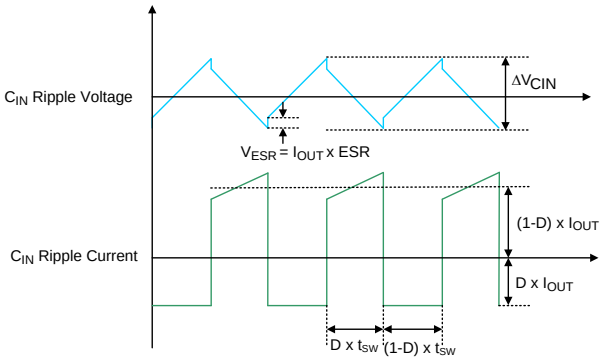


Figure 1. C_{IN} Ripple Voltage and Ripple Current

In addition, the input capacitor needs to have a very low ESR and must be rated to handle the worst-case RMS input current, which is given by:

$$I_{RMS} \cong I_{OUT_MAX} \times \frac{V_{OUT}}{V_{IN}} \times \sqrt{\frac{V_{IN}}{V_{OUT}} - 1}$$

It is common to use the worst-case $I_{RMS} \cong I_{OUT}/2$ at $V_{IN} = 2V_{OUT}$ for design. Note that ripple current ratings from capacitor manufacturers are often based on only 2000 hours of life, which makes it advisable to further de-rate the capacitor or choose a capacitor rated at a higher temperature than required.

Several capacitors may also be paralleled to meet size, height, and thermal requirements in the design. For low input voltage applications, sufficient bulk input capacitance is needed to minimize transient effects during output load changes.

Ceramic capacitors are ideal for switching regulator applications because of their small size, robustness, and very low ESR. However, care must be taken when using these capacitors at the input. A ceramic input capacitor combined with trace or cable inductance forms a high-quality (underdamped) tank circuit. If the RT6252A/B circuit is plugged into a live power supply, the input voltage can ring to twice its nominal value, possibly exceeding the

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

device's rated voltage. This situation is easily avoided by placing a low ESR ceramic input capacitor in parallel with a bulk capacitor with higher ESR to damp the voltage ringing.

The input capacitor should be placed as close as possible to the VIN pins, with a low inductance connection to the GND of the IC. In addition to a larger bulk capacitor, a small ceramic capacitor of 0.1μF should be placed close to the VIN and GND pins. This capacitor should be 0402 or 0603 in size.

18.3 Output Capacitor Selection

The RT6252A/B is optimized for ceramic output capacitors, and the best performance will be obtained using them. The total output capacitance value is usually determined by the desired output voltage ripple level and transient response requirements for sag (undershoot on positive load steps) and soar (overshoot on negative load steps).

18.4 Output Ripple

The output voltage ripple at the switching frequency is a function of the inductor current ripple passing through the output capacitor's impedance. To derive the output voltage ripple, the output capacitor's capacitance (COUT) and its equivalent series resistance (R_{ESR}) must be taken into consideration. The output peak-to-peak ripple voltage (V_{RIPPLE}) caused by the inductor current ripple (ΔI_L) is characterized by two components; ESR ripple ($V_{RIPPLE(ESR)}$) and capacitive ripple ($V_{RIPPLE(C)}$), and can be expressed as follows:

$$V_{RIPPLE} = V_{RIPPLE(ESR)} + V_{RIPPLE(C)}$$

$$V_{RIPPLE(ESR)} = \Delta I_L \times R_{ESR}$$

$$V_{RIPPLE(C)} = \frac{\Delta I_L}{8 \times C_{OUT} \times f_{SW}}$$

When ceramic capacitors are used, both parameters should be estimated due to the extremely low ESR and relatively small capacitance. Referring to the RT6252A/B's typical application circuit for a 1.2V application, the actual inductor current ripple (ΔI_L) is 0.85A, and the output capacitor is 2 x 22μF (Murata ceramic capacitor: GRM219R60J226ME47), V_{RIPPLE} can be obtained as follows:

The ripple caused by ESR (2mΩ) can be calculated as:

$V_{RIPPLE(ESR)}$ = 0.85A x 2mΩ = 1.7mV

Considering the capacitance derating, the effective capacitance is approximately 18μF when the output voltage is 1.2V, and another parameter is:

$$V_{RIPPLE(C)} = \frac{0.85A}{8 \times 2 \times 18\mu F \times 580kHz} = 5.1mV$$

$$V_{RIPPLE} = 1.7mV + 5.1mV = 6.8mV$$

18.5 Output Transient Undershoot and Overshoot

In addition to the voltage ripple at the switching frequency, the output capacitor and its ESR also affect the voltage sag (undershoot) and soar (overshoot) when the load steps up or down abruptly. The ACOT® transient response is very quick and output transients are usually small. The following section shows how to calculate the worst-case voltage swings in response to very fast load transients.

Both undershoot voltage and overshoot voltage consist of two factors: the voltage steps caused by the output capacitor's ESR and the voltage sag and soar due to the finite output capacitance and the inductor current slew rate. Use the following formulas to evaluate if the ESR is low enough (typically not a problem with ceramic capacitors) and the output capacitance is large enough to prevent excessive sag and soar on very fast load step edges with the chosen inductor value.

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

The amplitude of the ESR step, either up or down, is a function of the load step and the ESR of the output capacitor:

$V_{ESR_STEP} = \Delta I_{OUT} \times R_{ESR}$

The amplitude of the capacitive sag is a function of the load step, the output capacitor value, the inductor value, the input-to-output voltage differential, and the maximum duty cycle. The maximum duty cycle during a fast transient is a function of the on-time and the minimum off-time, since the ACOT® control scheme will ramp the current using on-times spaced apart with minimum off-times, which is as fast as allowed. Calculate the approximate on-time (neglecting parasitics) and maximum duty cycle for a given input and output voltage as follows:

$$t_{ON} = \frac{V_{OUT}}{V_{IN} \times f_{SW}} \text{ and } D_{MAX} = \frac{t_{ON}}{t_{ON} + t_{OFF_MIN}}$$

The real on-time will slightly extend due to the voltage drop related to the output current; however, this on-time compensation can be neglected. Additionally, the minimum on-time is 60ns (typical). If the calculated on-time is smaller than the minimum on-time, it and VOUT will both be clamped. Calculate the output voltage sag as follows:

$$V_{SAG} = \frac{L \times (\Delta I_{OUT})^2}{2 \times C_{OUT} \times \left(V_{IN(MIN)} \times D_{MAX} - V_{OUT}\right)}$$

The amplitude of the capacitive soar is a function of the load step, the output capacitor value, the inductor value, and the output voltage:

$$V_{SOAR} = \frac{L \times (\Delta I_{OUT})^2}{2 \times C_{OUT} \times V_{OUT}}$$

Because some modern digital loads can exhibit nearly instantaneous load changes, the amplitude of the ESR should be taken into consideration when calculating the V_{SAG} and V_{SOAR}.

18.6 Output Voltage Setting

Set the desired output voltage using a resistive divider from the output to ground, with the midpoint connected to FB. The output voltage is set according to the following equation:

$V_{OUT} = 0.765V \times (1 + R_{FB1} / R_{FB2})$

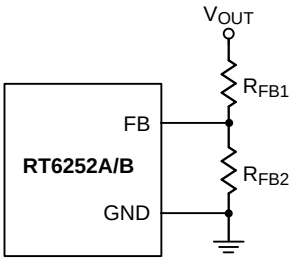


Figure 2. Output Voltage Setting

Place the FB resistors within 5mm of the FB pin. Choose R_{FB2} between 10kΩ and 100kΩ to minimize power consumption without excessive noise pickup and calculate R_{FB1} as follows:

$$R_{FB1} = \frac{R_{FB2} \times (V_{OUT} - V_{REF})}{V_{REF}}$$

For output voltage accuracy, use divider resistors with a tolerance of 1% or better.

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

18.7 Feed-Forward Capacitor Selection (C_{FF})

The RT6252A/B is optimized for low duty cycle applications and the control loop is stable with low ESR ceramic output capacitors. In higher duty cycle applications (higher output voltages or lower input voltages), the internal ripple signal will increase in amplitude. Before the ACOT® control loop can react to an output voltage fluctuation, the voltage change on the feedback signal must exceed the internal ripple amplitude. Due to the large internal ripple in this condition, the response may become slower and underdamped. This situation will result in a ringing waveform at the output terminal. In the case of high output voltage applications, the phenomenon described above is more visible due to the large attenuation in the feedback network. As shown in Figure 3, adding a feedforward capacitor (C_{FF}) across the upper feedback resistor is recommended. This increases the damping of the control system.

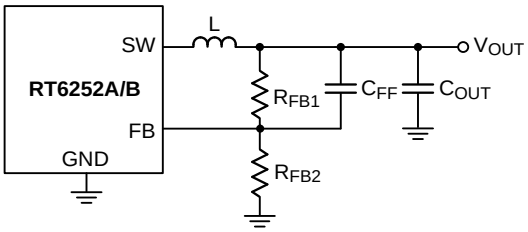


Figure 3. Feedback Loop with Feedforward Capacitor

Loop stability can be evaluated by observing the load transient response. A load step with a speed that exceeds the converter's bandwidth must be applied. For ACOT®, the loop bandwidth can be in the range of 100 to 200kHz, so a load step with a maximum rising time of 500ns (dI/dt ≈ 2A/μs) ensures the excitation frequency is sufficient. It is important that the converter operates in PWM mode, outside the light load efficiency range, and below any current-limit threshold. A load transient from 30% to 60% of the maximum load is reasonable, as shown in Figure 4.

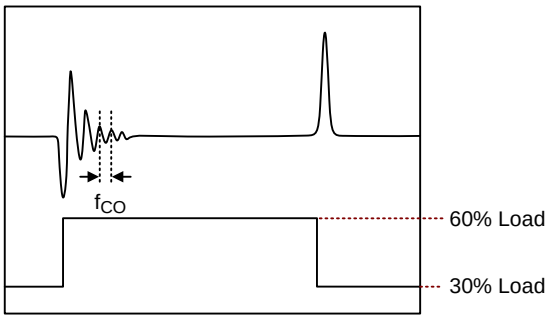


Figure 4. Example of Measuring the Converter BW by Fast Load Transient

C_{FF} can be calculated based on the following equation:

$$C_{FF} = \frac{1}{2\pi \times BW} \sqrt{\frac{1}{R_{FB1}} \times \left(\frac{1}{R_{FB1}} + \frac{1}{R_{FB2}} \right)}$$

Figure 5 shows the transient performance with and without a feedforward capacitor.

Note that after defining the C_{FF}, also evaluate the load regulation, because the feedforward capacitor might inject an offset voltage into V_{OUT}, causing V_{OUT} inaccuracy. If the output voltage is out of spec due to the calculated C_{FF}, evaluate decreasing the value of the feedforward capacitor C_{FF} or place a series resistor from C_{FF} to the FB pin.

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

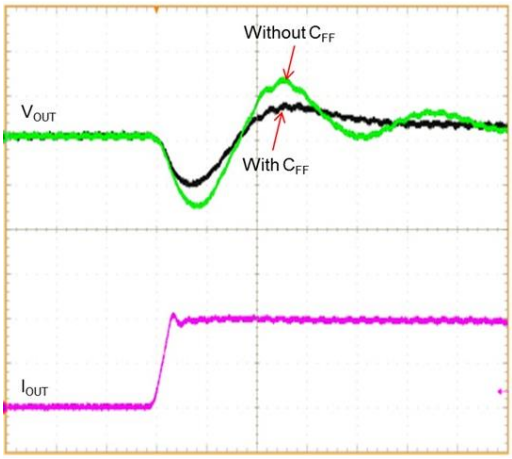


Figure 5. Load Transient Response with and without Feedforward Capacitor

18.8 Enable Operation

The RT6252A/B is enabled when the VIN pin voltage rises above V_{UVLO} and the EN pin voltage exceeds V_{EN_H}. The RT6252A/B is disabled when the VIN pin voltage falls below $V_{UVLO} – V_{UVLO_HYS}$ or when the EN pin voltage is below V_{EN_F}. An internal pull-down resistor R_{EN_PD}, which is connected from EN to GND, ensures that the chip remains in shutdown even if the EN pin is floated.

For automatic start-up, the EN pin, which has a high-voltage rating, can be connected directly to the input supply V_{IN}, as shown in Figure 6.

The built-in hysteresis band makes the EN pin useful for simple delay and timing circuits. The EN pin can be externally connected to VIN by adding a resistor R_{EN} and a capacitor C_{EN}, as shown in Figure 7, to introduce an additional delay. The time delay can be calculated using the equation below, based on the EN's internal threshold at which switching operation begins.

$$C_{EN} = \frac{t}{R_{th} \times \ln \frac{V_{th}}{V_{th} - V_{EN_H}}}$$

where

$R_{th} = R_{EN} // R_{EN_PD}$

$$V_{th} = V_{IN} \times \frac{R_{EN_PD}}{R_{EN_PD} + R_{EN}}$$

An external MOSFET can be used for logic control, as shown in Figure 8. In this case, R_{EN} is connected between VIN and the EN pin. The MOSFET Q1 will be controlled by logic to pull down the EN pin.

If it is desired to shut down the device using the EN pin before V_{IN} falls below the UVLO threshold, a resistive divider (R_{EN1} and R_{EN2}) can be used to externally set the input undervoltage-lockout threshold, as shown in Figure 9. For a given R_{EN1}, R_{EN2} can be found using the equation below for the desired V_{IN} stop voltage.

$$V_{IN_STOP} \times \frac{R_{EN2} // R_{EN_PD}}{R_{EN1} + R_{EN2} // R_{EN_PD}} < V_{EN_L}$$

After R_{EN1} and R_{EN2} are defined, the input voltage V_{IN_START} can be obtained from:

$$V_{EN_H} \times \frac{R_{EN1} + R_{EN2} // R_{EN_PD}}{R_{EN2} // R_{EN_PD}} = V_{IN_START}$$

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

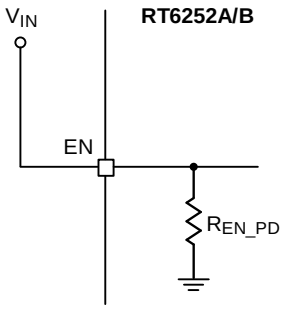


Figure 6. Automatic Start-Up Setting

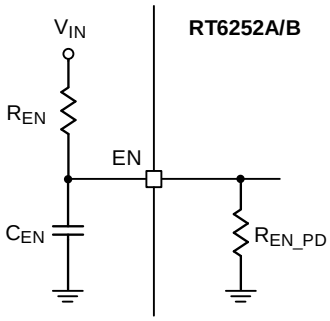


Figure 7. External Timing Control

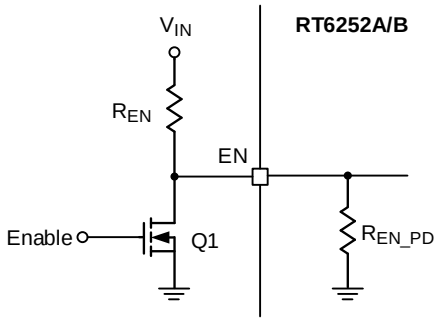


Figure 8. Digital Enable Control Circuit

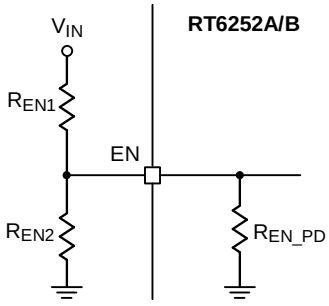


Figure 9. Resistor Divider for Lockout Threshold Setting

If V_{IN} shuts down faster than V_{OUT} and V_{OUT} is larger than 3.7V, the buck converter becomes a boost converter and generates negative current. To prevent this condition, EN should be shut down before V_{IN} falls below V_{OUT}. Therefore, a resistor divider for the lockout threshold is recommended.

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

18.9 Bootstrap Driver Supply

The bootstrap capacitor (C_{BOOT}) between the BOOT pin and the SW pin is used to create a voltage rail above the applied input voltage (V_{IN}). Specifically, the bootstrap capacitor is charged through an internal diode to a voltage approximately equal to PVCC each time the low-side switch is turned on. The charge on this capacitor is then used to supply the required current during the remainder of the switching cycle. For most applications, a 0.1μF, 0603 or 0402 ceramic capacitor is recommended, and the capacitor should have a 6.3 V or higher voltage rating.

18.10 External Bootstrap Diode (Optional)

A 0.1μF low-ESR ceramic bootstrap capacitor is connected between the BOOT and SW pins to supply the high-side gate driver. It is recommended to add an external bootstrap diode between an external 5V supply and the BOOT pin, as shown in Figure 10, to enhance efficiency when the input voltage is below 5.5V. The bootstrap diode can be a low-cost one, such as 1N4148 or BAT54. The external 5V can be a fixed 5V supply from the system, or a 5V output voltage generated by the RT6252A/B. Note that the BOOT voltage (V_{BOOT}) must be lower than 5.5V.

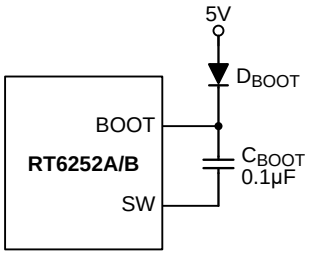


Figure 10. External Bootstrap Diode

18.11 External Bootstrap Resistor (Optional)

The gate driver of an internal power MOSFET, used as a high-side switch, is optimized for turning on the switch. The gate driver is not only fast enough to reduce switching power loss, but also slow enough to minimize EMI. The EMI issue is worse when the switch is turned on rapidly due to the induced high di/dt noise. When the high-side switch is turned off, the discharging time on the SW node is relatively slow because during the dead time, both the high-side and low-side MOSFETs are turned off. In some cases, it is desirable to reduce EMI further, even at the expense of additional power dissipation. The turn-on rate of the high-side switch can be slowed by placing a small bootstrap resistor, R_{BOOT}, between the BOOT pin and the external bootstrap capacitor, as shown in Figure 11. The recommended range for R_{BOOT} is several Ωs to 47 Ωs, and it can be 0402 or 0603 in size.

This will slow down the turn-on rate of the high-side switch and the rise rate of V_{SW}. To enhance EMI performance and enhance the internal MOSFET switch, the recommended application circuit, shown in Figure 12, includes an external bootstrap diode for charging the bootstrap capacitor and a bootstrap resistor, R_{BOOT}, placed between the BOOT pin and the capacitor/diode connection.

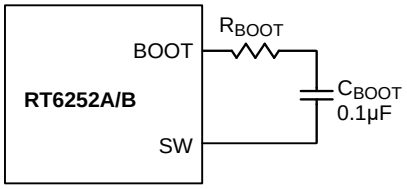


Figure 11. External Bootstrap Resistor at the BOOT Pin

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

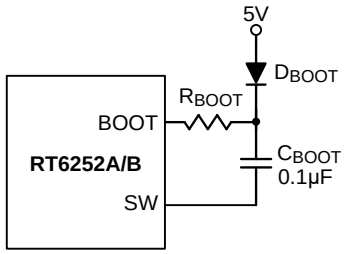


Figure 12. External Bootstrap Diode and Resistor at the BOOT Pin

18.12 Thermal Considerations

In many applications, the RT6252A/B does not generate much heat due to its high efficiency and the low thermal resistance of its TSOT-23-6(FC) package. However, in applications where the RT6252A/B runs at a high ambient temperature and high input voltage, the generated heat may exceed the maximum junction temperature of the part.

The RT6252A/B includes over-temperature protection (OTP) circuitry to prevent overheating due to excessive power dissipation. If the junction temperature reaches approximately 155°C, the RT6252A/B stops switching the power MOSFETs until the temperature cools down by 35°C.

Note that the over-temperature protection is intended to protect the device during momentary overload conditions. The protection is activated outside the absolute maximum range of operation as a secondary fail-safe and therefore should not be relied upon operationally. Continuous operation above the specified absolute maximum operating junction temperature may impair device reliability or permanently damage the device.

The maximum power dissipation can be calculated using the following formula:

$P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA(EFFECTIVE)}$

where $T_{J(MAX)}$ is the maximum allowed junction temperature of the die. For recommended operating conditions, the maximum junction temperature is 125°C. T_A is the ambient operating temperature, and $\theta_{JA(EFFECTIVE)}$ is the system-level junction-to-ambient thermal resistance. It can be estimated from thermal modeling or measurements in the system.

The thermal resistance of the device strongly depends on the surrounding PCB layout and can be enhanced by providing a heat sink with surrounding copper ground. The addition of backside copper with thermal vias, stiffeners, and other enhancements can also help reduce thermal resistance.

As an example, considering the case when the RT6252A is used in an application where V_{IN} = 12V, I_{OUT} = 2A, f_{SW} = 580kHz, and V_{OUT} = 5V. The efficiency at 5V, 2A is 91.3% when using WE-74404054047 (4.7µH, 30mΩ DCR) as the inductor and measured at room temperature. The core loss can be obtained from the manufacturer's website and it is 131mW. In this case, the power dissipation of the RT6252A is:

$$P_{D,\,RT} = \frac{1-\eta}{\eta} \times P_{OUT} - \left(I_O^2 \times DCR + P_{CORE}\right) = 0.702W$$

Considering the system-level $\theta_{JA(EFFECTIVE)}$ is 69.6°C/W (other heat sources are also considered), the junction temperature of the regulator operating in a 25°C ambient temperature is approximately:

T_J = 0.702W × 69.6°C/W + 25°C = 73.9°C

Figure 13 shows the RT6252A/B R_{DSON} versus different junction temperatures. If the application requires a higher ambient temperature, we might need to recalculate the device power dissipation and the junction temperature of the device based on a higher R_{DSON} since it increases with temperature.

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

Using a 35°C ambient temperature as an example. Since the variation of the junction temperature is dominated by the ambient temperature, the T_J' at a 35°C ambient temperature can be pre-estimated as:

$$T_J' = 73.9°C + (60°C - 25°C) = 108.9°C$$

According to Figure 13, the increase in R_{DSON} can be found as:

$$\Delta R_{DS(ON)_H} = 190m\Omega \text{ (at } 108.9°C) - 170m\Omega\ (73.9°C) = 20m\Omega$$

$$\Delta R_{DS(ON)_L} = 101m\Omega \text{ (at } 108.9°C) - 92m\Omega\ (73.9°C) = 9m\Omega$$

The external power dissipation caused by the increase in R_{DSON} at higher temperatures can be calculated as:

$$\Delta P_{D,RDS(ON)} = (2A)^2 \times \frac{5}{12} \times 20m\Omega + (2A)^2 \times \left(1 - \frac{5}{12}\right) \times 9m\Omega = 0.054W$$

As a result, the new power dissipation is 0.756W due to the variation in R_{DSON}. Therefore, the estimated new junction temperature is:

$$T_J' = 0.756W \times 69.6°C/W + 60°C = 112.6°C$$

If the application requires a higher ambient temperature that may exceed the recommended maximum junction temperature of 125°C, care should be taken to reduce the temperature rise of the part by using a heat sink or increasing air flow.

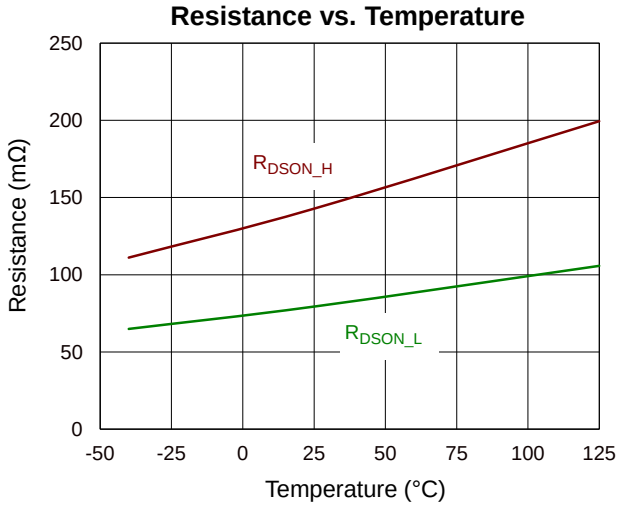


Figure 13. RT6252A/B R_{DSON} vs. Temperature

18.13 Layout Considerations

Follow the PCB layout guidelines below for optimal performance of the device.

- Keep the high-current paths short, especially at the ground terminals. This practice is essential for stable and jitter-free operation. The high-current path comprising the input capacitor, high-side FET, inductor, and output capacitor should be as short as possible. This practice is essential for high efficiency.
- Place the input MLCC capacitors as close to the VIN and GND pins as possible. The main MLCC capacitors should be placed on the same layer as the RT6252A/B.
- The SW node has a high-frequency voltage swing and should be kept to a small area. Keep analog components away from the SW node to prevent stray capacitive noise pickup.
- Connect the feedback network behind the output capacitors. Place the feedback components close to the FB pin.

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

- For better thermal performance, design a wide and thick plane for the GND pin or add a lot of vias to the GND plane.

An example of a PCB layout guide is shown in Figure 14.

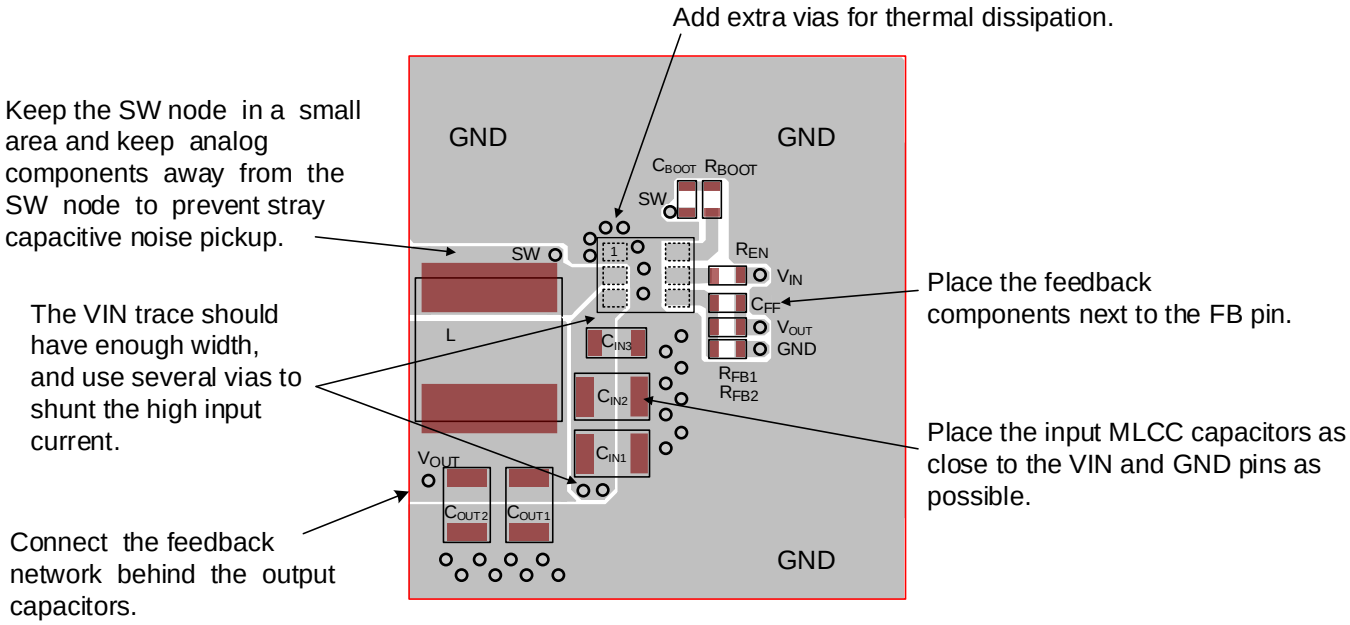


Figure 14. Layout Guide

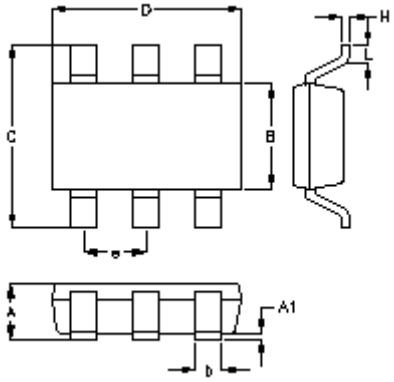
Note 8. The information provided in this section is for reference only. The customer is solely responsible for the designing, validating, and testing your product incorporating Richtek's product and ensure such product meets applicable standards and any safety, security, or other requirements.

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

19 Outline Dimension

19.1 TSOT-23-6 (FC)



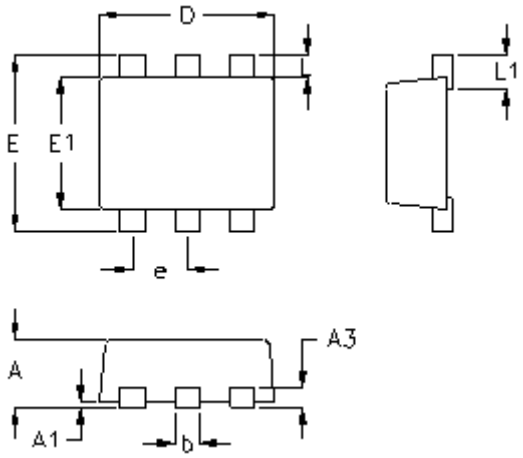
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.700	1.000	0.028	0.039
A1	0.000	0.100	0.000	0.004
B	1.397	1.803	0.055	0.071
b	0.300	0.559	0.012	0.022
C	2.591	3.000	0.102	0.118
D	2.692	3.099	0.106	0.122
e	0.950		0.037	
H	0.080	0.254	0.003	0.010
L	0.300	0.610	0.012	0.024

TSOT-23-6 (FC) Surface Mount Package

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

19.2 SOT-563 (FC)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.500	0.600	0.020	0.024
A1	0.000	0.050	0.000	0.002
A3	0.080	0.180	0.003	0.007
b	0.150	0.300	0.006	0.012
D	1.500	1.700	0.059	0.067
E	1.500	1.700	0.059	0.067
E1	1.100	1.300	0.043	0.051
e	0.500		0.020	
L	0.100	0.300	0.004	0.012
L1	0.200	0.400	0.008	0.016

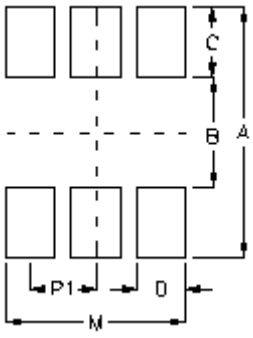
SOT-563 (FC) Surface Mount Package

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

20 Footprint Information

20.1 TSOT-23-6 (FC)

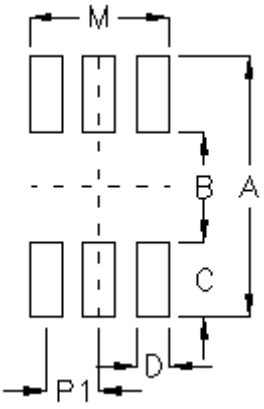


Package	Number of Pin	Footprint Dimension (mm)						Tolerance
		P1	A	B	C	D	M	
TSOT-26/TSOT-26(FC)/SOT-26/SOT-26(COL)	6	0.95	3.60	1.60	1.00	0.70	2.60	±0.10

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

20.2 SOT-563 (FC)



Package	Number of Pin	Footprint Dimension (mm)						Tolerance
		P1	A	B	C	D	M	
SOT-563(FC)	6	0.50	2.42	1.02	0.70	0.30	1.30	±0.10

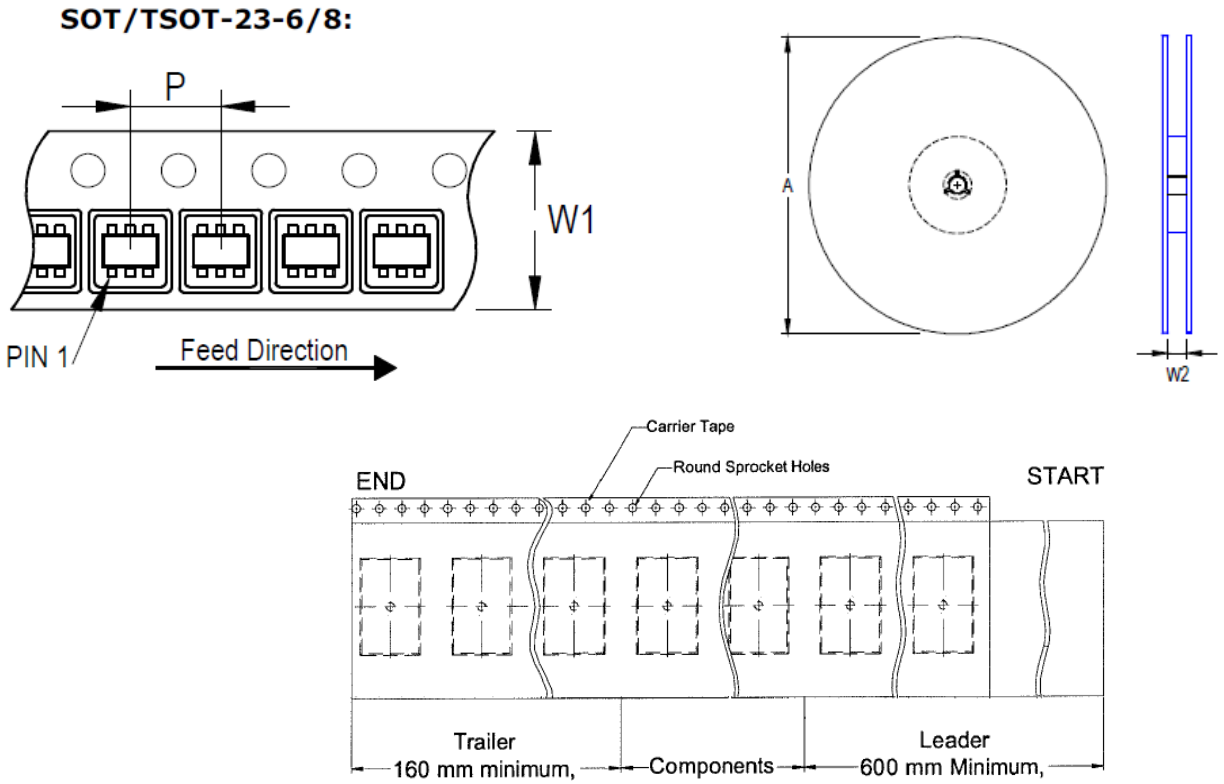
Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

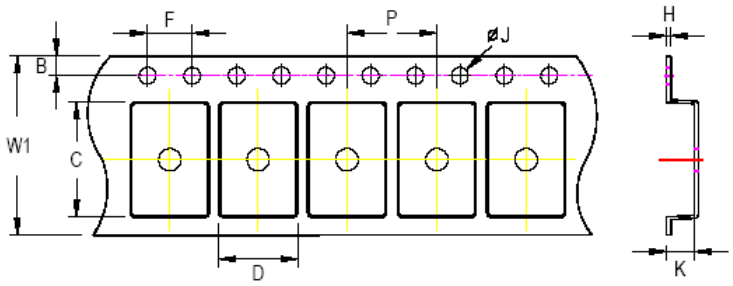
21 Packing Information

21.1 Tape and Reel Data

21.1.1 TSOT-23-6



Package Type	Tape Size (W1) (mm)	Pocket Pitch (P) (mm)	Reel Size (A)		Units per Reel	Trailer (mm)	Leader (mm)	Reel Width (W2) Min./Max. (mm)
			(mm)	(in)				
TSOT-23-6	8	4	180	7	3,000	160	600	8.4/9.9



C, D, and K are determined by component size. The clearance between the components and the cavity is as follows:

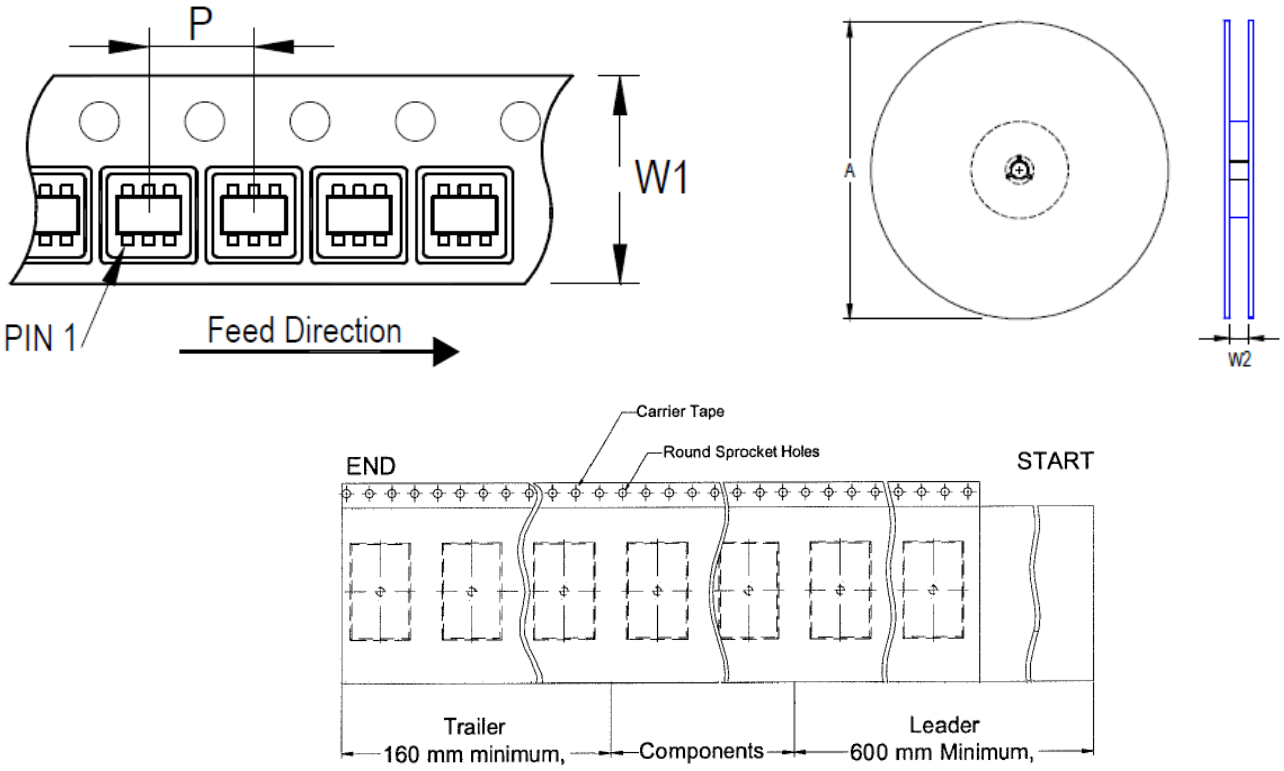
- For 8mm carrier tape: 0.5mm max.

Tape Size	W1	P		B		F		ØJ		K		H
	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Max.
8mm	8.3mm	3.9mm	4.1mm	1.65mm	1.85mm	3.9mm	4.1mm	1.5mm	1.6mm	1mm	1.2mm	0.6mm

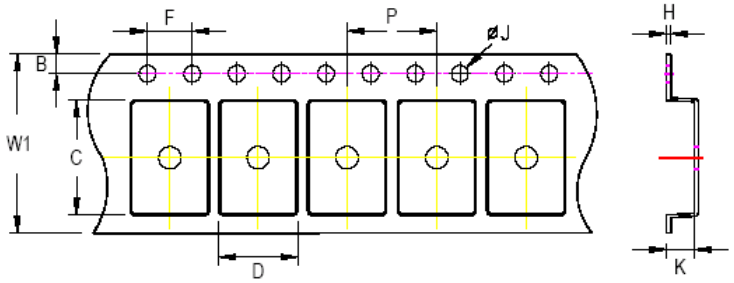
Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

21.1.2 SOT-563



Package Type	Tape Size (W1) (mm)	Pocket Pitch (P) (mm)	Reel Size (A)		Units per Reel	Trailer (mm)	Leader (mm)	Reel Width (W2) Min/Max (mm)
			(mm)	(in)				
SOT-563	8	4	180	7	5,000	160	600	8.4/9.9



C, D, and K are determined by component size. The clearance between the components and the cavity is as follows:

- For 8mm carrier tape: 0.5mm max.

Tape Size	W1	P		B		F		ØJ		K		H
	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Max.
8mm	8.3mm	3.9mm	4.1mm	1.65mm	1.85mm	3.9mm	4.1mm	1.5mm	1.6mm	0.65mm	0.85mm	0.6mm

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

21.2 Tape and Reel Packing

21.2.1 TSOT-23-6

Step	Photo/Description	Step	Photo/Description
1	 Reel 7”	4	 3 reels per inner box **Box A**
2	 HIC & Desiccant (1 Unit) inside	5	 12 inner boxes per outer box
3	 Caution label is on backside of Al bag	6	 Outer box **Carton A**

Container / Package	Reel		Box			Carton		
	Size	Units	Item	Reels	Units	Item	Boxes	Unit
TSOT-23-6	7”	3,000	Box A	3	9,000	Carton A	12	108,000
			Box E	1	3,000	For Combined or Partial Reel.		

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

21.2.2 SOT-563

Step	Photo/Description	Step	Photo/Description
1	 Reel 7”	4	 3 reels per inner box **Box A**
2	 HIC & Desiccant (1 Unit) inside	5	 12 inner boxes per outer box
3	 Caution label is on backside of Al bag	6	 Outer box **Carton A**

Container / Package	Reel		Box			Carton		
	Size	Units	Item	Reels	Units	Item	Boxes	Unit
SOT-563	7”	5,000	Box A	3	15,000	Carton A	12	180,000
			Box E	1	5,000	For Combined or Partial Reel.		

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

21.3 Packing Material Anti-ESD Property

Surface Resistance	Aluminum Bag	Reel	Cover tape	Carrier tape	Tube	Protection Band
Ω/cm^2	**10^4 to 10^{11}**	**10^4 to 10^{11}**	**10^4 to 10^{11}**	**10^4 to 10^{11}**	**10^4 to 10^{11}**	**10^4 to 10^{11}**

Richtek Technology Corporation
14F, No. 8, Tai Yuen 1st Street, Chupei City
Hsinchu, Taiwan, R.O.C.
Tel: (8863)5526789

Richtek products are sold by description only. Richtek reserves the right to change the circuitry and/or specifications without notice at any time. Customers should obtain the latest relevant information and data sheets before placing orders and should verify that such information is current and complete. Richtek cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Richtek product. Information furnished by Richtek is believed to be accurate and reliable. However, no responsibility is assumed by Richtek or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Richtek or its subsidiaries.

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.

22 Datasheet Revision History

Version	Date	Description	Item
03	2024/11/20	Modify	*General Description on page 1* *Features on page 1* *Ordering Information on page 2* *Functional Pin Description on page 4* *Electrical Characteristics on page 7, 8, 10* *Operation on page 20 to 23* *Application Information on page 24 to 34* *Packing Information on page 39 to 43* - Added packing information

Copyright © 2024 Richtek Technology Corporation. All rights reserved. RICHTEK is a registered trademark of Richtek Technology Corporation.

Downloaded from Arrow.com.